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# 9-Mbit (256K × 36/512K × 18) Flow-Through SRAM

## Features

- Supports 100 MHz, 133 MHz bus operations
- Supports 100 MHz bus operations (Automotive)
- 256K × 36/512K × 18 common I/O
- 3.3 V – 5% and +10% core power supply ( $V_{DD}$ )
- 2.5 V or 3.3 V I/O power supply ( $V_{DDQ}$ )
- Fast clock-to-output times
  - 6.5 ns (133-MHz version)
- Provide high performance 2-1-1 access rate
- User-selectable burst counter supporting Intel® Pentium® interleaved or linear burst sequences
- Separate processor and controller address strobes
- Synchronous self-timed write
- Asynchronous output enable
- Available in Pb-free 100-pin TQFP package, Pb-free 165-ball FBGA package and non Pb-free 119-ball BGA package
- TQFP available with 3-chip enable and 2-chip enable
- IEEE 1149.1 JTAG-compatible boundary scan
- “ZZ” sleep mode option

## Functional Description

The CY7C1361C/CY7C1363C is a 3.3 V, 256K × 36/512K × 18 synchronous flow-through SRAMs, respectively designed to interface with high speed microprocessors with minimum glue logic. Maximum access delay from clock rise is 6.5 ns (133 MHz version). A 2-bit on-chip counter captures the first address in a burst and increments the address automatically for the rest of the burst access. All synchronous inputs are gated by registers controlled by a positive-edge-triggered clock input (CLK). The synchronous inputs include all addresses, all data inputs, address-pipelining chip enable ( $CE_1$ ), depth-expansion chip enables ( $CE_2$  and  $CE_3^{(1)}$ ), burst control inputs (ADSC, ADSP, and ADV), write enables ( $BW_x$ , and BWE), and global write (GW). Asynchronous inputs include the output enable (OE) and the ZZ pin.

The CY7C1361C/CY7C1363C enables either interleaved or linear burst sequences, selected by the MODE input pin. A HIGH selects an interleaved burst sequence, while a LOW selects a linear burst sequence. Burst accesses can be initiated with the processor address strobe (ADSP) or the cache controller address strobe (ADSC) inputs. Address advancement is controlled by the address advancement (ADV) input.

Addresses and chip enables are registered at rising edge of clock when either address strobe processor (ADSP) or address strobe controller (ADSC) are active. Subsequent burst addresses can be internally generated as controlled by the advance pin (ADV).

The CY7C1361C/CY7C1363C operates from a +3.3 V core power supply while all outputs may operate with either a +2.5 or +3.3 V supply. All inputs and outputs are JEDEC-standard JESD8-5-compatible.

For a complete list of related documentation, click [here](#).

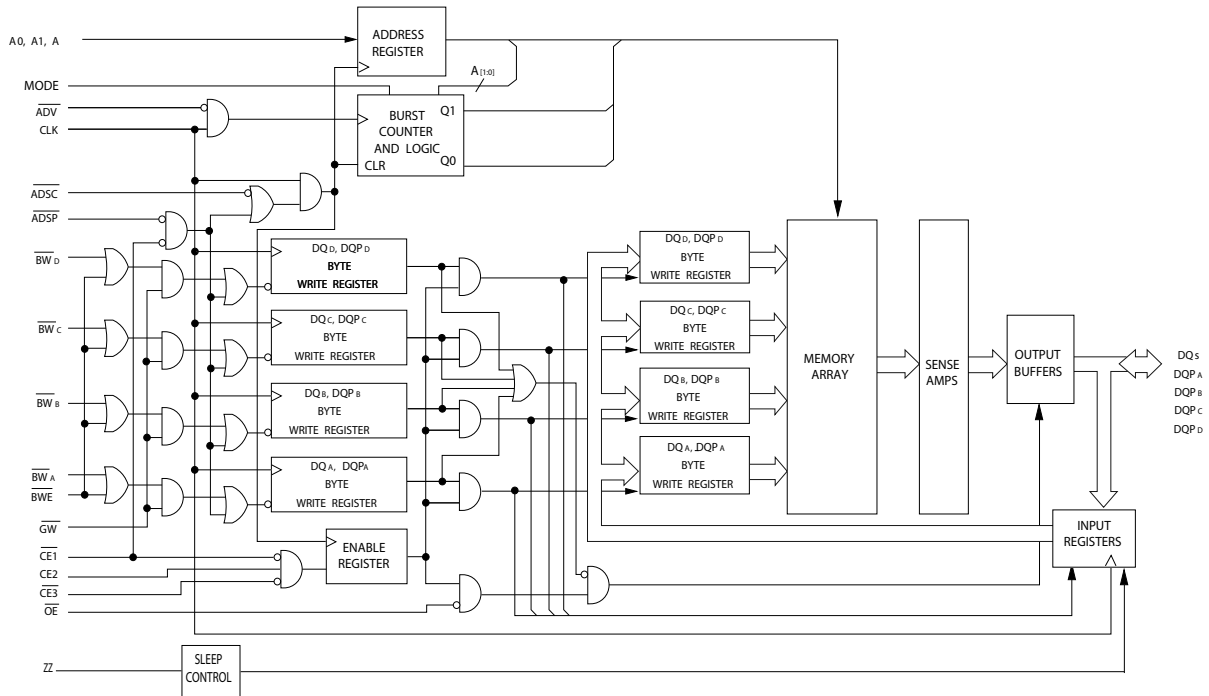
## Selection Guide

| Description                  |                       | 133 MHz | 100 MHz | Unit |
|------------------------------|-----------------------|---------|---------|------|
| Maximum access time          |                       | 6.5     | 8.5     | ns   |
| Maximum operating current    |                       | 250     | 180     | mA   |
| Maximum CMOS standby current | Commercial/Industrial | 40      | 40      | mA   |
|                              | Automotive            | –       | 60      | mA   |

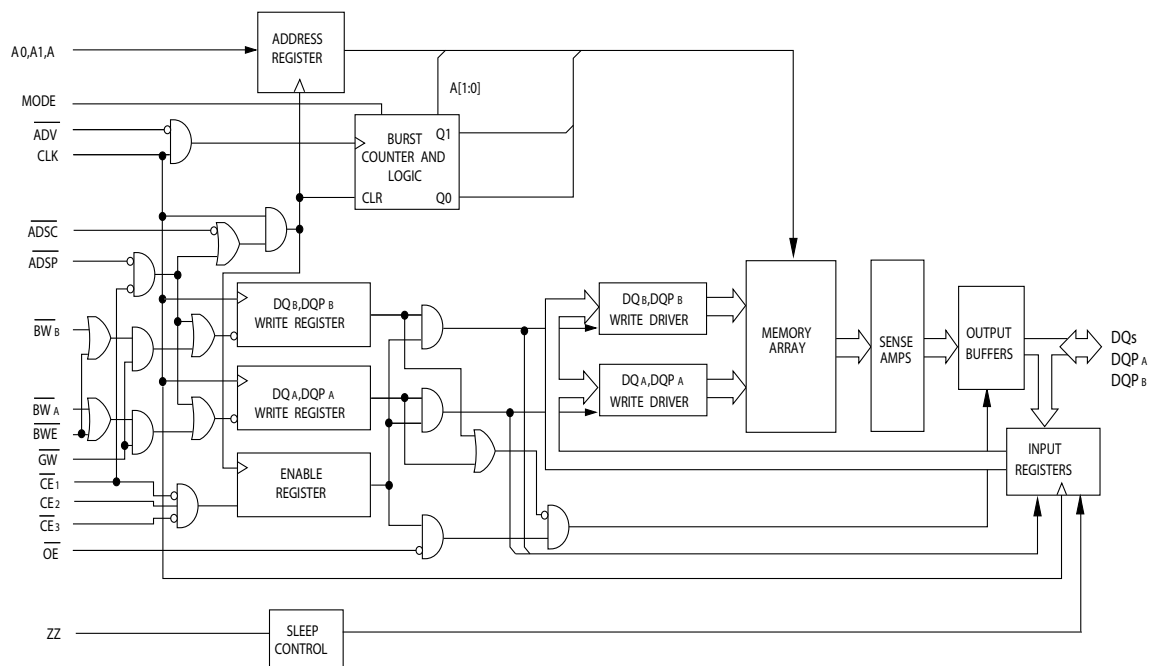
### Note

1.  $CE_3$  is for A version of 100-pin TQFP (3 Chip Enable Option). 119-ball BGA is offered only in 2 Chip Enable.

## Logic Block Diagram – CY7C1361C



## Logic Block Diagram – CY7C1363C

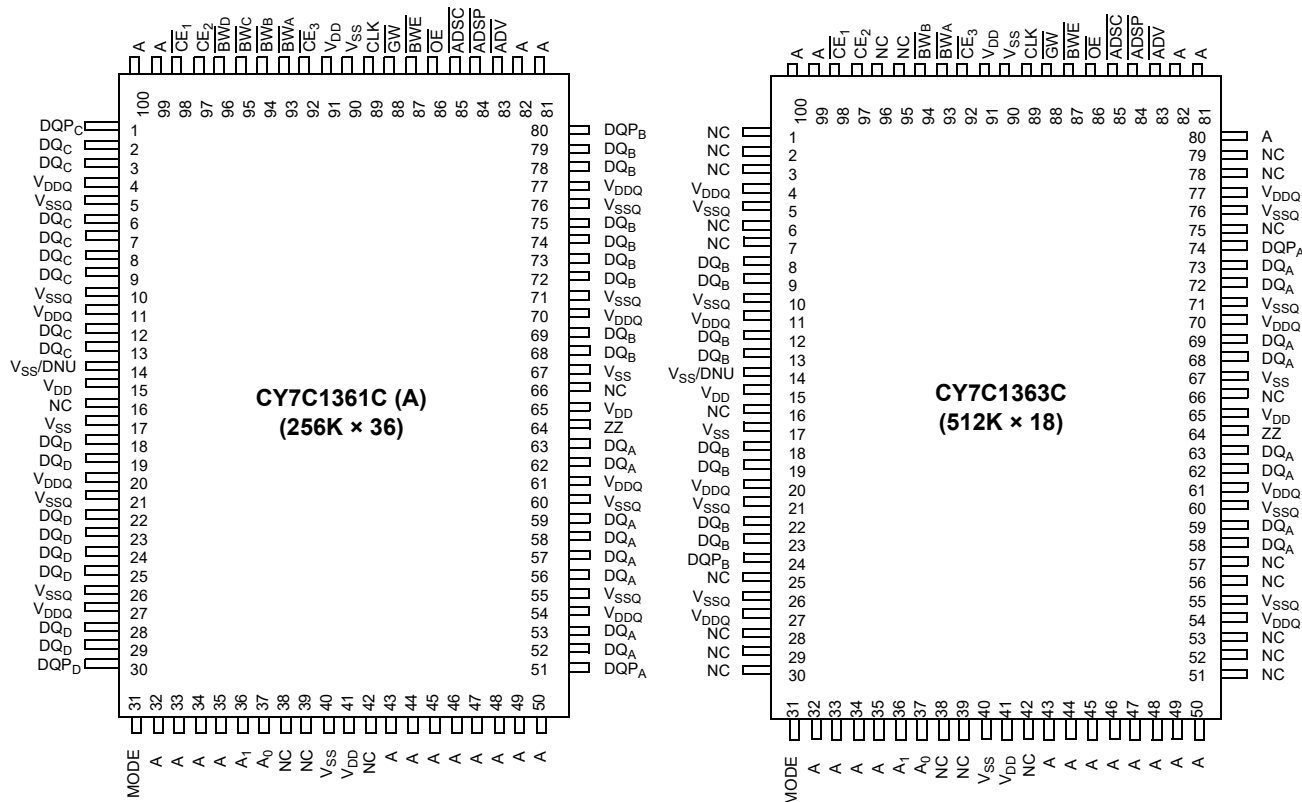


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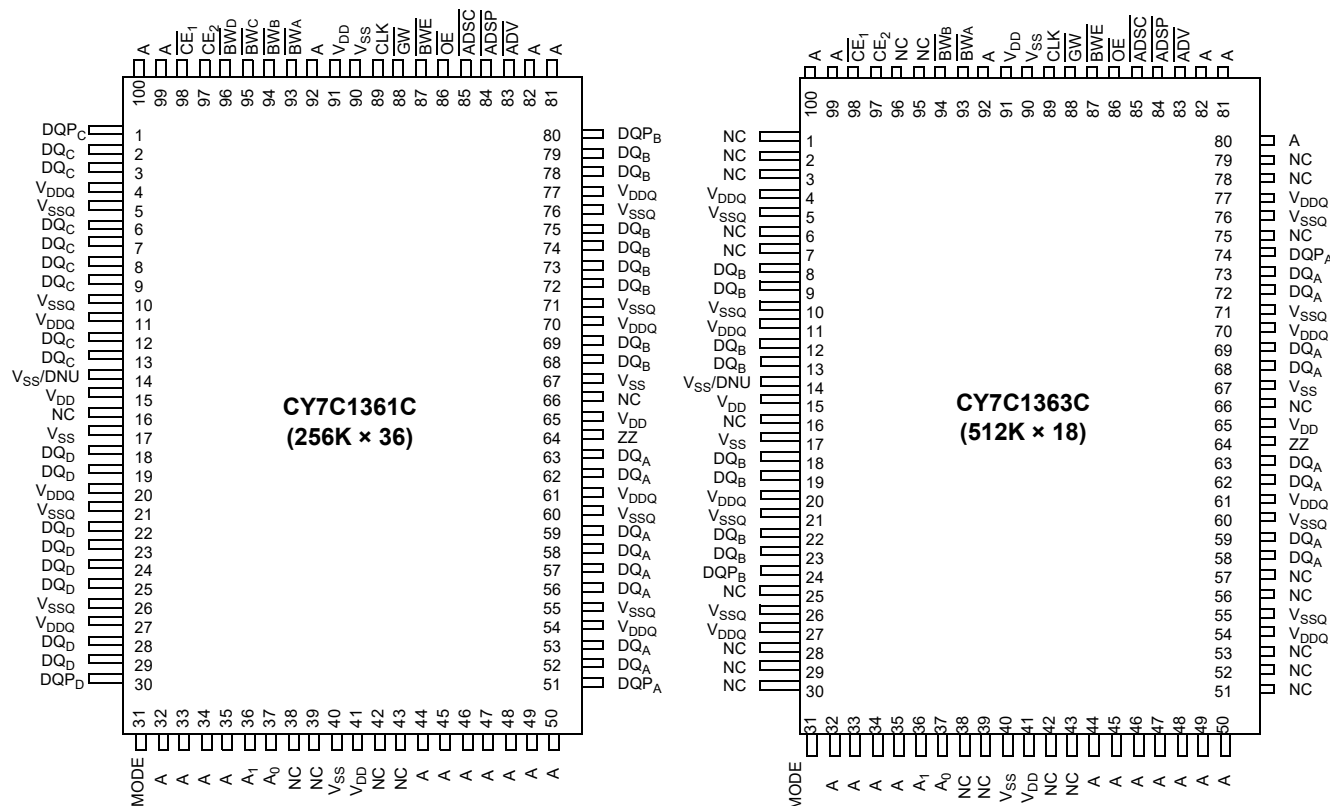
## Pin Configurations

Figure 1. 100-pin TQFP (14 × 20 × 1.4 mm) pinout (3 Chip Enables - A version)



## Pin Configurations *(continued)*

**Figure 2. 100-pin TQFP (14 × 20 × 1.4 mm) pinout (2 Chip Enables - AJ Version)**



## Pin Configurations *(continued)*

Figure 3. 119-ball BGA (14 × 22 × 2.4 mm) pinout (2 Chip Enables with JTAG)

| CY7C1361C (256K × 36) |                  |                  |                          |                          |                          |                  |                  |
|-----------------------|------------------|------------------|--------------------------|--------------------------|--------------------------|------------------|------------------|
|                       | 1                | 2                | 3                        | 4                        | 5                        | 6                | 7                |
| <b>A</b>              | V <sub>DDQ</sub> | A                | A                        | $\overline{\text{ADSP}}$ | A                        | A                | V <sub>DDQ</sub> |
| <b>B</b>              | NC/288M          | CE <sub>2</sub>  | A                        | $\overline{\text{ADSC}}$ | A                        | A                | NC/512M          |
| <b>C</b>              | NC/144M          | A                | A                        | V <sub>DD</sub>          | A                        | A                | NC/1G            |
| <b>D</b>              | DQ <sub>C</sub>  | DQP <sub>C</sub> | V <sub>SS</sub>          | NC                       | V <sub>SS</sub>          | DQP <sub>B</sub> | DQ <sub>B</sub>  |
| <b>E</b>              | DQ <sub>C</sub>  | DQ <sub>C</sub>  | V <sub>SS</sub>          | $\overline{\text{CE}}_1$ | V <sub>SS</sub>          | DQ <sub>B</sub>  | DQ <sub>B</sub>  |
| <b>F</b>              | V <sub>DDQ</sub> | DQ <sub>C</sub>  | V <sub>SS</sub>          | $\overline{\text{OE}}$   | V <sub>SS</sub>          | DQ <sub>B</sub>  | V <sub>DDQ</sub> |
| <b>G</b>              | DQ <sub>C</sub>  | DQ <sub>C</sub>  | $\overline{\text{BW}}_C$ | $\overline{\text{ADV}}$  | $\overline{\text{BW}}_B$ | DQ <sub>B</sub>  | DQ <sub>B</sub>  |
| <b>H</b>              | DQ <sub>C</sub>  | DQ <sub>C</sub>  | V <sub>SS</sub>          | $\overline{\text{GW}}$   | V <sub>SS</sub>          | DQ <sub>B</sub>  | DQ <sub>B</sub>  |
| <b>J</b>              | V <sub>DDQ</sub> | V <sub>DD</sub>  | NC                       | V <sub>DD</sub>          | NC                       | V <sub>DD</sub>  | V <sub>DDQ</sub> |
| <b>K</b>              | DQ <sub>D</sub>  | DQ <sub>D</sub>  | V <sub>SS</sub>          | CLK                      | V <sub>SS</sub>          | DQ <sub>A</sub>  | DQ <sub>A</sub>  |
| <b>L</b>              | DQ <sub>D</sub>  | DQ <sub>D</sub>  | $\overline{\text{BW}}_D$ | NC                       | $\overline{\text{BW}}_A$ | DQ <sub>A</sub>  | DQ <sub>A</sub>  |
| <b>M</b>              | V <sub>DDQ</sub> | DQ <sub>D</sub>  | V <sub>SS</sub>          | $\overline{\text{BWE}}$  | V <sub>SS</sub>          | DQ <sub>A</sub>  | V <sub>DDQ</sub> |
| <b>N</b>              | DQ <sub>D</sub>  | DQ <sub>D</sub>  | V <sub>SS</sub>          | A1                       | V <sub>SS</sub>          | DQ <sub>A</sub>  | DQ <sub>A</sub>  |
| <b>P</b>              | DQ <sub>D</sub>  | DQP <sub>D</sub> | V <sub>SS</sub>          | A0                       | V <sub>SS</sub>          | DQP <sub>A</sub> | DQ <sub>A</sub>  |
| <b>R</b>              | NC               | A                | MODE                     | V <sub>DD</sub>          | NC                       | A                | NC               |
| <b>T</b>              | NC               | NC/72M           | A                        | A                        | A                        | NC/36M           | ZZ               |
| <b>U</b>              | V <sub>DDQ</sub> | TMS              | TDI                      | TCK                      | TDO                      | NC               | V <sub>DDQ</sub> |

## Pin Configurations *(continued)*

**Figure 4. 165-ball FBGA pinout (3 Chip Enable)**

**CY7C1361C (256K × 36)**

|          | 1                | 2               | 3                 | 4                 | 5                 | 6                 | 7                | 8                 | 9                 | 10              | 11               |
|----------|------------------|-----------------|-------------------|-------------------|-------------------|-------------------|------------------|-------------------|-------------------|-----------------|------------------|
| <b>A</b> | NC/288M          | A               | $\overline{CE}_1$ | $\overline{BW}_C$ | $\overline{BW}_B$ | $\overline{CE}_3$ | $\overline{BWE}$ | $\overline{ADSC}$ | $\overline{ADV}$  | A               | NC               |
| <b>B</b> | NC/144M          | A               | $\overline{CE}_2$ | $\overline{BW}_D$ | $\overline{BW}_A$ | CLK               | $\overline{GW}$  | $\overline{OE}$   | $\overline{ADSP}$ | A               | NC/576M          |
| <b>C</b> | DQP <sub>C</sub> | NC              | V <sub>DDQ</sub>  | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>  | V <sub>SS</sub>   | V <sub>DDQ</sub>  | NC/1G           | DQP <sub>B</sub> |
| <b>D</b> | DQ <sub>C</sub>  | DQ <sub>C</sub> | V <sub>DDQ</sub>  | V <sub>DD</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>  | V <sub>DD</sub>   | V <sub>DDQ</sub>  | DQ <sub>B</sub> | DQ <sub>B</sub>  |
| <b>E</b> | DQ <sub>C</sub>  | DQ <sub>C</sub> | V <sub>DDQ</sub>  | V <sub>DD</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>  | V <sub>DD</sub>   | V <sub>DDQ</sub>  | DQ <sub>B</sub> | DQ <sub>B</sub>  |
| <b>F</b> | DQ <sub>C</sub>  | DQ <sub>C</sub> | V <sub>DDQ</sub>  | V <sub>DD</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>  | V <sub>DD</sub>   | V <sub>DDQ</sub>  | DQ <sub>B</sub> | DQ <sub>B</sub>  |
| <b>G</b> | DQ <sub>C</sub>  | DQ <sub>C</sub> | V <sub>DDQ</sub>  | V <sub>DD</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>  | V <sub>DD</sub>   | V <sub>DDQ</sub>  | DQ <sub>B</sub> | DQ <sub>B</sub>  |
| <b>H</b> | NC               | NC              | NC                | V <sub>DD</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>  | V <sub>DD</sub>   | NC                | NC              | ZZ               |
| <b>J</b> | DQ <sub>D</sub>  | DQ <sub>D</sub> | V <sub>DDQ</sub>  | V <sub>DD</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>  | V <sub>DD</sub>   | V <sub>DDQ</sub>  | DQ <sub>A</sub> | DQ <sub>A</sub>  |
| <b>K</b> | DQ <sub>D</sub>  | DQ <sub>D</sub> | V <sub>DDQ</sub>  | V <sub>DD</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>  | V <sub>DD</sub>   | V <sub>DDQ</sub>  | DQ <sub>A</sub> | DQ <sub>A</sub>  |
| <b>L</b> | DQ <sub>D</sub>  | DQ <sub>D</sub> | V <sub>DDQ</sub>  | V <sub>DD</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>  | V <sub>DD</sub>   | V <sub>DDQ</sub>  | DQ <sub>A</sub> | DQ <sub>A</sub>  |
| <b>M</b> | DQ <sub>D</sub>  | DQ <sub>D</sub> | V <sub>DDQ</sub>  | V <sub>DD</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>  | V <sub>DD</sub>   | V <sub>DDQ</sub>  | DQ <sub>A</sub> | DQ <sub>A</sub>  |
| <b>N</b> | DQP <sub>D</sub> | NC              | V <sub>DDQ</sub>  | V <sub>SS</sub>   | NC                | NC/18M            | NC               | V <sub>SS</sub>   | V <sub>DDQ</sub>  | NC              | DQP <sub>A</sub> |
| <b>P</b> | NC               | NC/72M          | A                 | A                 | TDI               | A1                | TDO              | A                 | A                 | A               | A                |
| <b>R</b> | MODE             | NC/36M          | A                 | A                 | TMS               | A0                | TCK              | A                 | A                 | A               | A                |



## Pin Definitions

| Name                                                                 | I/O                | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |
|----------------------------------------------------------------------|--------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| A <sub>0</sub> , A <sub>1</sub> , A                                  | Input-synchronous  | <b>Address inputs used to select one of the address locations.</b> Sampled at the rising edge of the CLK if ADSP or ADSC is active LOW, and $\overline{CE}_1$ , CE <sub>2</sub> , and CE <sub>3</sub> <sup>[2]</sup> are sampled active. A <sub>[1:0]</sub> feed the 2-bit counter.                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
| $\overline{BW}_A, \overline{BW}_B, \overline{BW}_C, \overline{BW}_D$ | Input-synchronous  | <b>Byte write select inputs, active LOW.</b> Qualified with $\overline{BWE}$ to conduct byte writes to the SRAM. Sampled on the rising edge of CLK.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
| $\overline{GW}$                                                      | Input-synchronous  | <b>Global write enable input, active LOW.</b> When asserted LOW on the rising edge of CLK, a global write is conducted (all bytes are written, regardless of the values on $\overline{BW}_X$ and $\overline{BWE}$ ).                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |
| CLK                                                                  | Input-clock        | <b>Clock input.</b> Used to capture all synchronous inputs to the device. Also used to increment the burst counter when $\overline{ADV}$ is asserted LOW, during a burst operation.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
| $\overline{CE}_1$                                                    | Input-synchronous  | <b>Chip enable 1 input, active LOW.</b> Sampled on the rising edge of CLK. Used in conjunction with CE <sub>2</sub> and CE <sub>3</sub> <sup>[2]</sup> to select/deselect the device. ADSP is ignored if $\overline{CE}_1$ is HIGH. $\overline{CE}_1$ is sampled only when a new external address is loaded.                                                                                                                                                                                                                                                                                                                                                                                                                                         |
| CE <sub>2</sub>                                                      | Input-synchronous  | <b>Chip enable 2 input, active HIGH.</b> Sampled on the rising edge of CLK. Used in conjunction with $\overline{CE}_1$ and CE <sub>3</sub> <sup>[2]</sup> to select/deselect the device. CE <sub>2</sub> is sampled only when a new external address is loaded.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| CE <sub>3</sub> <sup>[2]</sup>                                       | Input-synchronous  | <b>Chip enable 3 input, active LOW.</b> Sampled on the rising edge of CLK. Used in conjunction with $\overline{CE}_1$ and CE <sub>2</sub> to select/deselect the device. CE <sub>3</sub> is sampled only when a new external address is loaded.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| $\overline{OE}$                                                      | Input-asynchronous | <b>Output enable, asynchronous input, active LOW.</b> Controls the direction of the I/O pins. When LOW, the I/O pins behave as outputs. When deasserted HIGH, I/O pins are tristated, and act as input data pins. $\overline{OE}$ is masked during the first clock of a read cycle when emerging from a deselected state.                                                                                                                                                                                                                                                                                                                                                                                                                            |
| $\overline{ADV}$                                                     | Input-synchronous  | <b>Advance input signal, sampled on the rising edge of CLK.</b> When asserted, it automatically increments the address in a burst cycle.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| ADSP                                                                 | Input-synchronous  | <b>Address strobe from processor, sampled on the rising edge of CLK, active LOW.</b> When asserted LOW, addresses presented to the device are captured in the address registers. A <sub>[1:0]</sub> are also loaded into the burst counter. When ADSP and ADSC are both asserted, only ADSP is recognized. ADSP is ignored when $\overline{CE}_1$ is deasserted HIGH.                                                                                                                                                                                                                                                                                                                                                                                |
| ADSC                                                                 | Input-synchronous  | <b>Address strobe from controller, sampled on the rising edge of CLK, active LOW.</b> When asserted LOW, addresses presented to the device are captured in the address registers. A <sub>[1:0]</sub> are also loaded into the burst counter. When ADSP and ADSC are both asserted, only ADSP is recognized.                                                                                                                                                                                                                                                                                                                                                                                                                                          |
| $\overline{BWE}$                                                     | Input-synchronous  | <b>Byte write enable input, active LOW.</b> Sampled on the rising edge of CLK. This signal must be asserted LOW to conduct a byte write.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| ZZ                                                                   | Input-asynchronous | <b>ZZ “sleep” input, active HIGH.</b> When asserted HIGH places the device in a non-time-critical “sleep” condition with data integrity preserved. For normal operation, this pin has to be LOW or left floating. ZZ pin has an internal pull down.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
| DQ <sub>s</sub>                                                      | I/O-synchronous    | <b>Bidirectional data I/O lines.</b> As inputs, they feed into an on-chip data register that is triggered by the rising edge of CLK. As outputs, they deliver the data contained in the memory location specified by the addresses presented during the previous clock rise of the read cycle. The direction of the pins is controlled by $\overline{OE}$ . When $\overline{OE}$ is asserted LOW, the pins behave as outputs. When HIGH, DQ <sub>s</sub> and DQP <sub>x</sub> are placed in a tristate condition. The outputs are automatically tristated during the data portion of a write sequence, during the first clock when emerging from a deselected state, and when the device is deselected, regardless of the state of $\overline{OE}$ . |
| DQP <sub>x</sub>                                                     | I/O-synchronous    | <b>Bidirectional data parity I/O lines.</b> Functionally, these signals are identical to DQ <sub>s</sub> . During write sequences, DQP <sub>x</sub> is controlled by $\overline{BW}_X$ correspondingly.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
| MODE                                                                 | Input-static       | <b>Selects burst order.</b> When tied to GND selects linear burst sequence. When tied to V <sub>DD</sub> or left floating selects interleaved burst sequence. This is a strap pin and should remain static during device operation. Mode Pin has an internal pull-up.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
| V <sub>DD</sub>                                                      | Power supply       | <b>Power supply inputs to the core of the device.</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |

### Note

2. CE<sub>3</sub> is for A version of 100-pin TQFP (3 Chip Enable Option). 119-ball BGA is offered only in 2 Chip Enable.

## Pin Definitions *(continued)*

| Name                 | I/O                            | Description                                                                                                                                                                                                                                                |
|----------------------|--------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| V <sub>DDQ</sub>     | I/O power supply               | <b>Power supply for the I/O circuitry.</b>                                                                                                                                                                                                                 |
| V <sub>SS</sub>      | Ground                         | <b>Ground for the core of the device.</b>                                                                                                                                                                                                                  |
| V <sub>SSQ</sub>     | I/O ground                     | <b>Ground for the I/O circuitry.</b>                                                                                                                                                                                                                       |
| TDO                  | JTAG serial output synchronous | <b>Serial data-out to the JTAG circuit.</b> Delivers data on the negative edge of TCK. If the JTAG feature is not being used, this pin should be left unconnected. This pin is not available on TQFP packages.                                             |
| TDI                  | JTAG serial input synchronous  | <b>Serial data-in to the JTAG circuit.</b> Sampled on the rising edge of TCK. If the JTAG feature is not being used, this pin can be left floating or connected to V <sub>DD</sub> through a pull up resistor. This pin is not available on TQFP packages. |
| TMS                  | JTAG serial input synchronous  | <b>Serial data-in to the JTAG circuit.</b> Sampled on the rising edge of TCK. If the JTAG feature is not being used, this pin can be disconnected or connected to V <sub>DD</sub> . This pin is not available on TQFP packages.                            |
| TCK                  | JTAG-clock                     | <b>Clock input to the JTAG circuitry.</b> If the JTAG feature is not being used, this pin must be connected to V <sub>SS</sub> . This pin is not available on TQFP packages.                                                                               |
| NC                   | –                              | <b>No connects.</b> Not internally connected to the die. 18M, 36M, 72M, 144M, 288M, 576M, and 1G are address expansion pins and are not internally connected to the die.                                                                                   |
| V <sub>SS</sub> /DNU | Ground/DNU                     | This pin can be connected to ground or should be left floating.                                                                                                                                                                                            |

## Functional Overview

All synchronous inputs pass through input registers controlled by the rising edge of the clock. Maximum access delay from the clock rise ( $t_{CDV}$ ) is 6.5 ns (133 MHz device).

The CY7C1361C/CY7C1363C supports secondary cache in systems using either a linear or interleaved burst sequence. The interleaved burst order supports Pentium and i486™ processors. The linear burst sequence is suited for processors that use a linear burst sequence. The burst order is user-selectable, and is determined by sampling the MODE input. Accesses can be initiated with either the processor address strobe (ADSP) or the controller address strobe (ADSC). Address advancement through the burst sequence is controlled by the ADV input. A two-bit on-chip wraparound burst counter captures the first address in a burst sequence and automatically increments the address for the rest of the burst access.

Byte write operations are qualified with the byte write enable (BWE) and byte write select (BW<sub>X</sub>) inputs. A global write enable (GW) overrides all byte write inputs and writes data to all four bytes. All writes are simplified with on-chip synchronous self-timed write circuitry.

Three synchronous chip selects ( $\overline{CE}_1$ , CE<sub>2</sub>,  $\overline{CE}_3$ <sup>[3]</sup>) and an asynchronous output enable (OE) provide for easy bank selection and output tristate control. ADSP is ignored if CE<sub>1</sub> is HIGH.

## Single Read Accesses

A single read access is initiated when the following conditions are satisfied at clock rise: (1)  $\overline{CE}_1$ , CE<sub>2</sub>, and CE<sub>3</sub><sup>[3]</sup> are all asserted active and (2) ADSP or ADSC is asserted LOW (if the access is initiated by ADSC, the write inputs must be deasserted during this first cycle). The address presented to the address inputs is latched into the address register and the burst counter/control logic and presented to the memory core. If the OE input is asserted LOW, the requested data will be available at the data outputs a maximum to  $t_{CDV}$  after clock rise. ADSP is ignored if CE<sub>1</sub> is HIGH.

## Single Write Accesses Initiated by ADSP

This access is initiated when the following conditions are satisfied at clock rise: (1)  $\overline{CE}_1$ , CE<sub>2</sub>, CE<sub>3</sub><sup>[3]</sup> are all asserted active and (2) ADSP is asserted LOW. The addresses presented are loaded into the address register and the burst inputs (GW, BWE, and BW<sub>X</sub>) are ignored during this first clock cycle. If the write inputs are asserted active (see [Partial Truth Table for Read/Write on page 12](#) for appropriate states that indicate a write) on the next clock rise, the appropriate data will be latched and written into the device. Byte writes are allowed. All I/Os are tristated during a byte write. Since this is a common I/O device, the asynchronous OE input signal must be deasserted and the I/Os must be tristated prior to the presentation of data to DQs. As a safety precaution, the data lines are tristated once a write cycle is detected, regardless of the state of OE.

### Note

3. CE<sub>3</sub> is for A version of 100-pin TQFP (3 Chip Enable Option). 119-ball BGA is offered only in 2 Chip Enable.

### Single Write Accesses Initiated by $\overline{\text{ADSC}}$

This write access is initiated when the following conditions are satisfied at clock rise: (1)  $\overline{\text{CE}}_1$ ,  $\overline{\text{CE}}_2$ , and  $\overline{\text{CE}}_3^{[4]}$  are all asserted active, (2)  $\overline{\text{ADSC}}$  is asserted LOW, (3)  $\overline{\text{ADSP}}$  is deasserted HIGH, and (4) the write input signals ( $\overline{\text{GW}}$ ,  $\overline{\text{BWE}}$ , and  $\overline{\text{BW}}_X$ ) indicate a write access.  $\overline{\text{ADSC}}$  is ignored if  $\overline{\text{ADSP}}$  is active LOW.

The addresses presented are loaded into the address register and the burst counter/control logic and delivered to the memory core. The information presented to  $\text{DQ}_{[A:D]}$  is written into the specified address location. Byte writes are allowed. All I/Os are tristated when a write is detected, even a byte write. Since this is a common I/O device, the asynchronous  $\overline{\text{OE}}$  input signal must be deasserted and the I/Os must be tristated prior to the presentation of data to  $\text{DQ}_S$ . As a safety precaution, the data lines are tristated once a write cycle is detected, regardless of the state of  $\overline{\text{OE}}$ .

### Burst Sequences

The CY7C1361C/CY7C1363C provides an on-chip two-bit wraparound burst counter inside the SRAM. The burst counter is fed by  $A_{[1:0]}$ , and can follow either a linear or interleaved burst order. The burst order is determined by the state of the MODE input. A LOW on MODE will select a linear burst sequence. A HIGH on MODE selects an interleaved burst order. Leaving MODE unconnected causes the device to default to a interleaved burst sequence.

### Sleep Mode

The ZZ input pin is an asynchronous input. Asserting ZZ places the SRAM in a power conservation 'sleep' mode. Two clock cycles are required to enter into or exit from this 'sleep' mode. While in this mode, data integrity is guaranteed. Accesses

pending when entering the 'sleep' mode are not considered valid nor is the completion of the operation guaranteed. The device must be deselected prior to entering the 'sleep' mode.  $\overline{\text{CE}}_1$ ,  $\overline{\text{CE}}_2$ ,  $\overline{\text{CE}}_3^{[4]}$ ,  $\overline{\text{ADSP}}$ , and  $\overline{\text{ADSC}}$  must remain inactive for the duration of  $t_{\text{ZZREC}}$  after the ZZ input returns LOW.

### Interleaved Burst Address Table

(MODE = Floating or  $V_{\text{DD}}$ )

| First Address<br>A1:A0 | Second Address<br>A1:A0 | Third Address<br>A1:A0 | Fourth Address<br>A1:A0 |
|------------------------|-------------------------|------------------------|-------------------------|
| 00                     | 01                      | 10                     | 11                      |
| 01                     | 00                      | 11                     | 10                      |
| 10                     | 11                      | 00                     | 01                      |
| 11                     | 10                      | 01                     | 00                      |

### Linear Burst Address Table

(MODE = GND)

| First Address<br>A1:A0 | Second Address<br>A1:A0 | Third Address<br>A1:A0 | Fourth Address<br>A1:A0 |
|------------------------|-------------------------|------------------------|-------------------------|
| 00                     | 01                      | 10                     | 11                      |
| 01                     | 10                      | 11                     | 00                      |
| 10                     | 11                      | 00                     | 01                      |
| 11                     | 00                      | 01                     | 10                      |

### ZZ Mode Electrical Characteristics

| Parameter          | Description                       | Test Conditions                                |                       | Min               | Max               | Unit |
|--------------------|-----------------------------------|------------------------------------------------|-----------------------|-------------------|-------------------|------|
| $I_{\text{DDZZ}}$  | Sleep mode standby current        | $\text{ZZ} \geq V_{\text{DD}} - 0.2 \text{ V}$ | Commercial/Industrial | –                 | 50                | mA   |
|                    |                                   |                                                | Automotive            | –                 | 60                | mA   |
| $t_{\text{ZZS}}$   | Device operation to ZZ            | $\text{ZZ} \geq V_{\text{DD}} - 0.2 \text{ V}$ |                       | –                 | $2t_{\text{CYC}}$ | ns   |
| $t_{\text{ZZREC}}$ | ZZ recovery time                  | $\text{ZZ} \leq 0.2 \text{ V}$                 |                       | $2t_{\text{CYC}}$ | –                 | ns   |
| $t_{\text{ZZI}}$   | ZZ active to sleep current        | This parameter is sampled                      |                       | –                 | $2t_{\text{CYC}}$ | ns   |
| $t_{\text{RZZI}}$  | ZZ Inactive to exit sleep current | This parameter is sampled                      |                       | 0                 | –                 | ns   |

#### Note

4.  $\overline{\text{CE}}_3$  is for A version of 100-pin TQFP (3 Chip Enable Option). 119-ball BGA is offered only in 2 Chip Enable.

## Truth Table

The Truth Table for CY7C1361C and CY7C1363C follows. [5, 6, 7, 8, 9]

| Cycle Description            | Address Used | $\overline{CE}_1$ | $CE_2$ | $\overline{CE}_3$ | ZZ | $\overline{ADSP}$ | $\overline{ADSC}$ | $\overline{ADV}$ | $\overline{WRITE}$ | $\overline{OE}$ | CLK | DQ        |
|------------------------------|--------------|-------------------|--------|-------------------|----|-------------------|-------------------|------------------|--------------------|-----------------|-----|-----------|
| Deselected cycle, power-down | None         | H                 | X      | X                 | L  | X                 | L                 | X                | X                  | X               | L-H | Tri-state |
| Deselected cycle, power-down | None         | L                 | L      | X                 | L  | L                 | X                 | X                | X                  | X               | L-H | Tri-state |
| Deselected cycle, power-down | None         | L                 | X      | H                 | L  | L                 | X                 | X                | X                  | X               | L-H | Tri-state |
| Deselected cycle, power-down | None         | L                 | L      | X                 | L  | H                 | L                 | X                | X                  | X               | L-H | Tri-state |
| Deselected cycle, power-down | None         | X                 | X      | H                 | L  | H                 | L                 | X                | X                  | X               | L-H | Tri-state |
| Sleep mode, power-down       | None         | X                 | X      | X                 | H  | X                 | X                 | X                | X                  | X               | X   | Tri-state |
| Read cycle, begin burst      | External     | L                 | H      | L                 | L  | L                 | X                 | X                | X                  | L               | L-H | Q         |
| Read cycle, begin burst      | External     | L                 | H      | L                 | L  | L                 | X                 | X                | X                  | H               | L-H | Tri-state |
| Write cycle, begin burst     | External     | L                 | H      | L                 | L  | H                 | L                 | X                | L                  | X               | L-H | D         |
| Read cycle, begin burst      | External     | L                 | H      | L                 | L  | H                 | L                 | X                | H                  | L               | L-H | Q         |
| Read cycle, begin burst      | External     | L                 | H      | L                 | L  | H                 | L                 | X                | H                  | H               | L-H | Tri-state |
| Read cycle, continue burst   | Next         | X                 | X      | X                 | L  | H                 | H                 | L                | H                  | L               | L-H | Q         |
| Read cycle, continue burst   | Next         | X                 | X      | X                 | L  | H                 | H                 | L                | H                  | H               | L-H | Tri-state |
| Read cycle, continue burst   | Next         | H                 | X      | X                 | L  | X                 | H                 | L                | H                  | L               | L-H | Q         |
| Read cycle, continue burst   | Next         | H                 | X      | X                 | L  | X                 | H                 | L                | H                  | H               | L-H | Tri-state |
| Write cycle, continue burst  | Next         | X                 | X      | X                 | L  | H                 | H                 | L                | L                  | X               | L-H | D         |
| Write cycle, continue burst  | Next         | H                 | X      | X                 | L  | X                 | H                 | L                | L                  | X               | L-H | D         |
| Read cycle, suspend burst    | Current      | X                 | X      | X                 | L  | H                 | H                 | H                | H                  | L               | L-H | Q         |
| Read cycle, suspend burst    | Current      | X                 | X      | X                 | L  | H                 | H                 | H                | H                  | H               | L-H | Tri-state |
| Read cycle, suspend burst    | Current      | H                 | X      | X                 | L  | X                 | H                 | H                | H                  | L               | L-H | Q         |
| Read cycle, suspend burst    | Current      | H                 | X      | X                 | L  | X                 | H                 | H                | H                  | H               | L-H | Tri-state |
| Write cycle, suspend burst   | Current      | X                 | X      | X                 | L  | H                 | H                 | H                | L                  | X               | L-H | D         |
| Write cycle, suspend burst   | Current      | H                 | X      | X                 | L  | X                 | H                 | H                | L                  | X               | L-H | D         |

### Notes

- X = "Don't Care." H = Logic HIGH, L = Logic LOW.
- $\overline{WRITE}$  = L when any one or more byte write enable signals and  $\overline{BWE}$  = L or  $\overline{GW}$  = L.  $\overline{WRITE}$  = H when all byte write enable signals,  $\overline{BWE}$ ,  $\overline{GW}$  = H.
- The DQ pins are controlled by the current cycle and the OE signal. OE is asynchronous and is not sampled with the clock.
- The SRAM always initiates a read cycle when ADSP is asserted, regardless of the state of  $\overline{GW}$ ,  $\overline{BWE}$ , or  $\overline{BW}_X$ . Writes may occur only on subsequent clocks after the ADSP or with the assertion of ADSC. As a result, OE must be driven HIGH prior to the start of the write cycle to allow the outputs to tri-state. OE is a don't care for the remainder of the write cycle.
- OE is asynchronous and is not sampled with the clock rise. It is masked internally during write cycles. During a read cycle all data bits are tri-state when OE is inactive or when the device is deselected, and all data bits behave as output when OE is active (LOW).

## Partial Truth Table for Read/Write

The Partial Truth Table for Read/Write for CY7C1361C follows. [10, 11]

| Function (CY7C1361C)                                                           | $\overline{GW}$ | $\overline{BWE}$ | $\overline{BW}_D$ | $\overline{BW}_C$ | $\overline{BW}_B$ | $\overline{BW}_A$ |
|--------------------------------------------------------------------------------|-----------------|------------------|-------------------|-------------------|-------------------|-------------------|
| Read                                                                           | H               | H                | X                 | X                 | X                 | X                 |
| Read                                                                           | H               | L                | H                 | H                 | H                 | H                 |
| Write byte (A, DQP <sub>A</sub> )                                              | H               | L                | H                 | H                 | H                 | L                 |
| Write byte (B, DQP <sub>B</sub> )                                              | H               | L                | H                 | H                 | L                 | H                 |
| Write bytes (B, A, DQP <sub>A</sub> , DQP <sub>B</sub> )                       | H               | L                | H                 | H                 | L                 | L                 |
| Write byte (C, DQP <sub>C</sub> )                                              | H               | L                | H                 | L                 | H                 | H                 |
| Write bytes (C, A, DQP <sub>C</sub> , DQP <sub>A</sub> )                       | H               | L                | H                 | L                 | H                 | L                 |
| Write bytes (C, B, DQP <sub>C</sub> , DQP <sub>B</sub> )                       | H               | L                | H                 | L                 | L                 | H                 |
| Write bytes (C, B, A, DQP <sub>C</sub> , DQP <sub>B</sub> , DQP <sub>A</sub> ) | H               | L                | H                 | L                 | L                 | L                 |
| Write byte (D, DQP <sub>D</sub> )                                              | H               | L                | L                 | H                 | H                 | H                 |
| Write bytes (D, A, DQP <sub>D</sub> , DQP <sub>A</sub> )                       | H               | L                | L                 | H                 | H                 | L                 |
| Write bytes (D, B, DQP <sub>D</sub> , DQP <sub>B</sub> )                       | H               | L                | L                 | H                 | L                 | H                 |
| Write bytes (D, B, A, DQP <sub>D</sub> , DQP <sub>B</sub> , DQP <sub>A</sub> ) | H               | L                | L                 | H                 | L                 | L                 |
| Write bytes (D, B, DQP <sub>D</sub> , DQP <sub>B</sub> )                       | H               | L                | L                 | L                 | H                 | H                 |
| Write bytes (D, B, A, DQP <sub>D</sub> , DQP <sub>C</sub> , DQP <sub>A</sub> ) | H               | L                | L                 | L                 | H                 | L                 |
| Write bytes (D, C, A, DQP <sub>D</sub> , DQP <sub>B</sub> , DQP <sub>A</sub> ) | H               | L                | L                 | L                 | L                 | H                 |
| Write all bytes                                                                | H               | L                | L                 | L                 | L                 | L                 |
| Write all bytes                                                                | L               | X                | X                 | X                 | X                 | X                 |

## Partial Truth Table for Read/Write

The Partial Truth Table for Read/Write for CY7C1363C follows. [10, 11]

| Function (CY7C1363C)                                   | $\overline{GW}$ | $\overline{BWE}$ | $\overline{BW}_B$ | $\overline{BW}_A$ |
|--------------------------------------------------------|-----------------|------------------|-------------------|-------------------|
| Read                                                   | H               | H                | X                 | X                 |
| Read                                                   | H               | L                | H                 | H                 |
| Write byte A – (DQ <sub>A</sub> and DQP <sub>A</sub> ) | H               | L                | H                 | L                 |
| Write byte B – (DQ <sub>B</sub> and DQP <sub>B</sub> ) | H               | L                | L                 | H                 |
| Write all bytes                                        | H               | L                | L                 | L                 |
| Write all bytes                                        | L               | X                | X                 | X                 |

### Notes

10. X = "Don't Care." H = Logic HIGH, L = Logic LOW.

11. Table only lists a partial listing of the byte write combinations. Any Combination of  $\overline{BW}_X$  is valid Appropriate write will be done based on which byte write is active.

## IEEE 1149.1 Serial Boundary Scan (JTAG)

The CY7C1361C incorporates a serial boundary scan test access port (TAP) in the BGA package only. The TQFP package does not offer this functionality. This part operates in accordance with IEEE Standard 1149.1-1900, but does not have the set of functions required for full 1149.1 compliance. These functions from the IEEE specification are excluded because their inclusion places an added delay in the critical speed path of the SRAM. Note that the TAP controller functions in a manner that does not conflict with the operation of other devices using 1149.1 fully compliant TAPs. The TAP operates using JEDEC-standard 3.3 V or 2.5 V I/O logic levels.

The CY7C1361C contains a TAP controller, instruction register, boundary scan register, bypass register, and ID register.

### Disabling the JTAG Feature

It is possible to operate the SRAM without using the JTAG feature. To disable the TAP controller, TCK must be tied LOW ( $V_{SS}$ ) to prevent clocking of the device. TDI and TMS are internally pulled up and may be unconnected. They may alternately be connected to  $V_{DD}$  through a pull-up resistor. TDO should be left unconnected. Upon power up, the device comes up in a reset state which does not interfere with the operation of the device.

### Test Access Port (TAP)

#### Test Clock (TCK)

The test clock is used only with the TAP controller. All inputs are captured on the rising edge of TCK. All outputs are driven from the falling edge of TCK.

#### Test Mode Select (TMS)

The TMS input is used to give commands to the TAP controller and is sampled on the rising edge of TCK. It is allowable to leave this ball unconnected if the TAP is not used. The ball is pulled up internally, resulting in a logic HIGH level.

#### Test Data-In (TDI)

The TDI ball is used to serially input information into the registers and can be connected to the input of any of the registers. The register between TDI and TDO is chosen by the instruction that is loaded into the TAP instruction register. For information about loading the instruction register, see the [TAP Controller State Diagram on page 15](#). TDI is internally pulled up and can be unconnected if the TAP is unused in an application. TDI is connected to the most significant bit (MSB) of any register.

#### Test Data-Out (TDO)

The TDO output ball is used to serially clock data-out from the registers. The output is active depending upon the current state of the TAP state machine (see [Instruction Codes on page 19](#)). The output changes on the falling edge of TCK. TDO is connected to the least significant bit (LSB) of any register.

### Performing a TAP Reset

A RESET is performed by forcing TMS HIGH ( $V_{DD}$ ) for five rising edges of TCK. This RESET does not affect the operation of the SRAM and may be performed while the SRAM is operating.

At power up, the TAP is reset internally to ensure that TDO comes up in a high Z state.

### TAP Registers

Registers are connected between the TDI and TDO balls and allow data to be scanned into and out of the SRAM test circuitry. Only one register can be selected at a time through the instruction register. Data is serially loaded into the TDI ball on the rising edge of TCK. Data is output on the TDO ball on the falling edge of TCK.

#### Instruction Register

Three-bit instructions can be serially loaded into the instruction register. This register is loaded when it is placed between the TDI and TDO balls as shown in the [TAP Controller Block Diagram on page 16](#). Upon power-up, the instruction register is loaded with the IDCODE instruction. It is also loaded with the IDCODE instruction if the controller is placed in a reset state as described in the previous section.

When the TAP controller is in the Capture-IR state, the two least significant bits are loaded with a binary '01' pattern to enable fault isolation of the board-level serial test data path.

#### Bypass Register

To save time when serially shifting data through registers, it is sometimes advantageous to skip certain chips. The bypass register is a single-bit register that can be placed between the TDI and TDO balls. This enables data to be shifted through the SRAM with minimal delay. The bypass register is set LOW ( $V_{SS}$ ) when the BYPASS instruction is executed.

#### Boundary Scan Register

The boundary scan register is connected to all the input and bidirectional balls on the SRAM.

The boundary scan register is loaded with the contents of the RAM I/O ring when the TAP controller is in the Capture-DR state and is then placed between the TDI and TDO balls when the controller is moved to the Shift-DR state. The EXTEST, SAMPLE/PRELOAD, and SAMPLE Z instructions can be used to capture the contents of the I/O ring.

The [Boundary Scan Order on page 20](#) show the order in which the bits are connected. Each bit corresponds to one of the bumps on the SRAM package. The MSB of the register is connected to TDI and the LSB is connected to TDO.

#### Identification (ID) Register

The ID register is loaded with a vendor-specific, 32-bit code during the Capture-DR state when the IDCODE command is loaded in the instruction register. The IDCODE is hardwired into the SRAM and can be shifted out when the TAP controller is in the Shift-DR state. The ID register has a vendor code and other information described in [Identification Register Definitions on page 19](#).



## TAP Instruction Set

### Overview

Eight different instructions are possible with the three-bit instruction register. All combinations are listed in the [Instruction Codes on page 19](#). Three of these instructions are listed as RESERVED and should not be used. The other five instructions are described in detail in this section.

The TAP controller used in this SRAM is not fully compliant to the 1149.1 convention because some of the mandatory 1149.1 instructions are not fully implemented.

The TAP controller cannot be used to load address data or control signals into the SRAM and cannot preload the I/O buffers. The SRAM does not implement the 1149.1 commands EXTEST or INTEST or the PRELOAD portion of SAMPLE/PRELOAD; rather, it performs a capture of the I/O ring when these instructions are executed.

Instructions are loaded into the TAP controller during the Shift-IR state when the instruction register is placed between TDI and TDO. During this state, instructions are shifted through the instruction register through the TDI and TDO balls. To execute the instruction once it is shifted in, the TAP controller needs to be moved into the Update-IR state.

### EXTEST

EXTEST is a mandatory 1149.1 instruction which is to be executed whenever the instruction register is loaded with all 0s. EXTEST is not implemented in this SRAM TAP controller, and therefore this device is not compliant to 1149.1. The TAP controller does not recognize an all-0 instruction.

When an EXTEST instruction is loaded into the instruction register, the SRAM responds as if a SAMPLE/PRELOAD instruction has been loaded. There is one difference between the two instructions. Unlike the SAMPLE/PRELOAD instruction, EXTEST places the SRAM outputs in a high Z state.

### IDCODE

The IDCODE instruction causes a vendor-specific, 32-bit code to be loaded into the instruction register. It also places the instruction register between the TDI and TDO balls and enables the IDCODE to be shifted out of the device when the TAP controller enters the Shift-DR state.

The IDCODE instruction is loaded into the instruction register upon power-up or whenever the TAP controller is given a test logic reset state.

### SAMPLE Z

The SAMPLE Z instruction causes the boundary scan register to be connected between the TDI and TDO balls when the TAP

controller is in a Shift-DR state. It also places all SRAM outputs into a high Z state.

### SAMPLE/PRELOAD

SAMPLE/PRELOAD is a 1149.1-mandatory instruction. When the SAMPLE/PRELOAD instructions are loaded into the instruction register and the TAP controller is in the Capture-DR state, a snapshot of data on the inputs and output pins is captured in the boundary scan register.

The user must be aware that the TAP controller clock can only operate at a frequency up to 20 MHz, while the SRAM clock operates more than an order of magnitude faster. Because there is a large difference in the clock frequencies, it is possible that during the Capture-DR state, an input or output undergoes a transition. The TAP may then try to capture a signal while in transition (metastable state). This does not harm the device, but there is no guarantee as to the value that will be captured. Repeatable results may not be possible.

To guarantee that the boundary scan register captures the correct value of a signal, the SRAM signal must be stabilized long enough to meet the TAP controller's capture setup plus hold times ( $t_{CS}$  and  $t_{CH}$ ). The SRAM clock input might not be captured correctly if there is no way in a design to stop (or slow) the clock during a SAMPLE/PRELOAD instruction. If this is an issue, it is still possible to capture all other signals and simply ignore the value of the CK and CK# captured in the boundary scan register.

After the data is captured, it is possible to shift out the data by putting the TAP into the Shift-DR state. This places the boundary scan register between the TDI and TDO pins.

PRELOAD enables an initial data pattern to be placed at the latched parallel outputs of the boundary scan register cells prior to the selection of another boundary scan test operation.

The shifting of data for the SAMPLE and PRELOAD phases can occur concurrently when required - that is, while data captured is shifted out, the preloaded data can be shifted in.

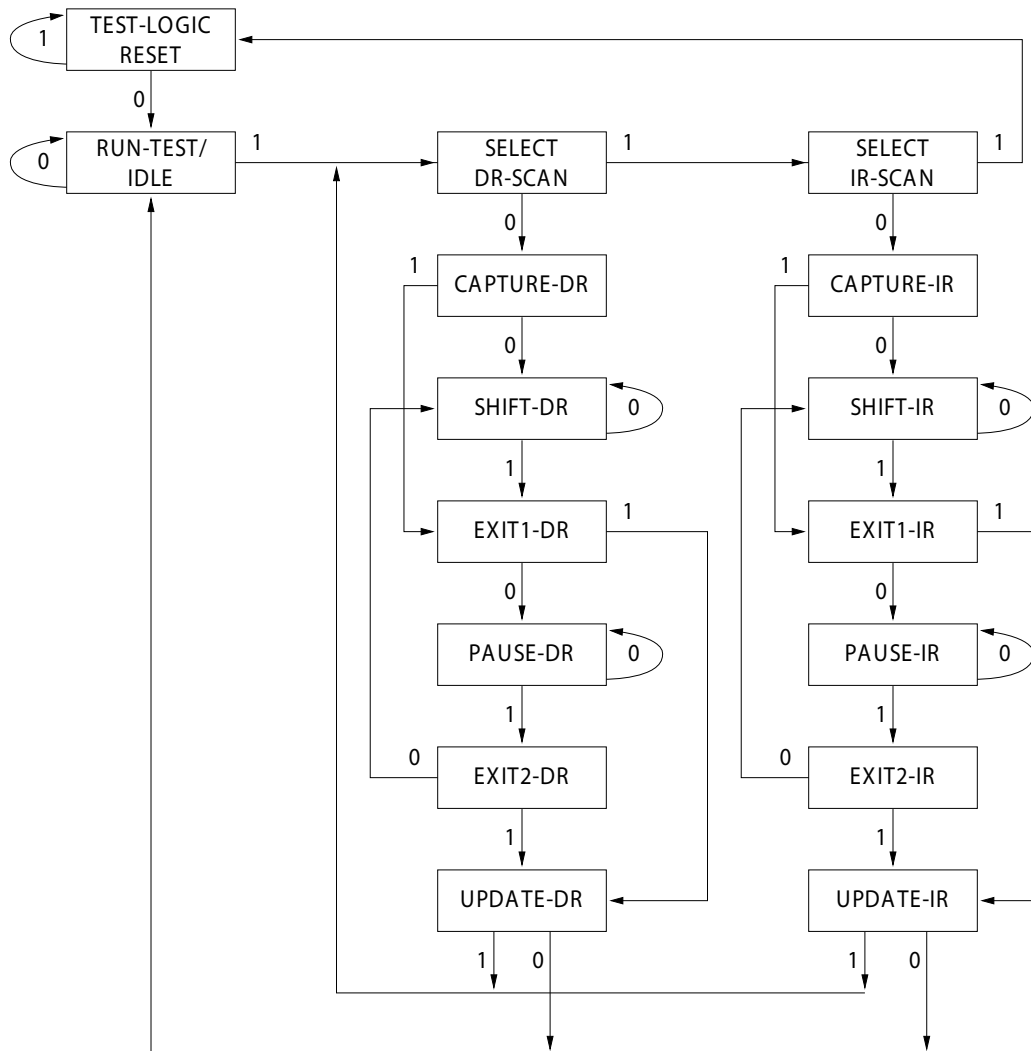
### BYPASS

When the BYPASS instruction is loaded in the instruction register and the TAP is placed in a Shift-DR state, the bypass register is placed between the TDI and TDO balls. The advantage of the BYPASS instruction is that it shortens the boundary scan path when multiple devices are connected together on a board.

### Reserved

These instructions are not implemented but are reserved for future use. Do not use these instructions.

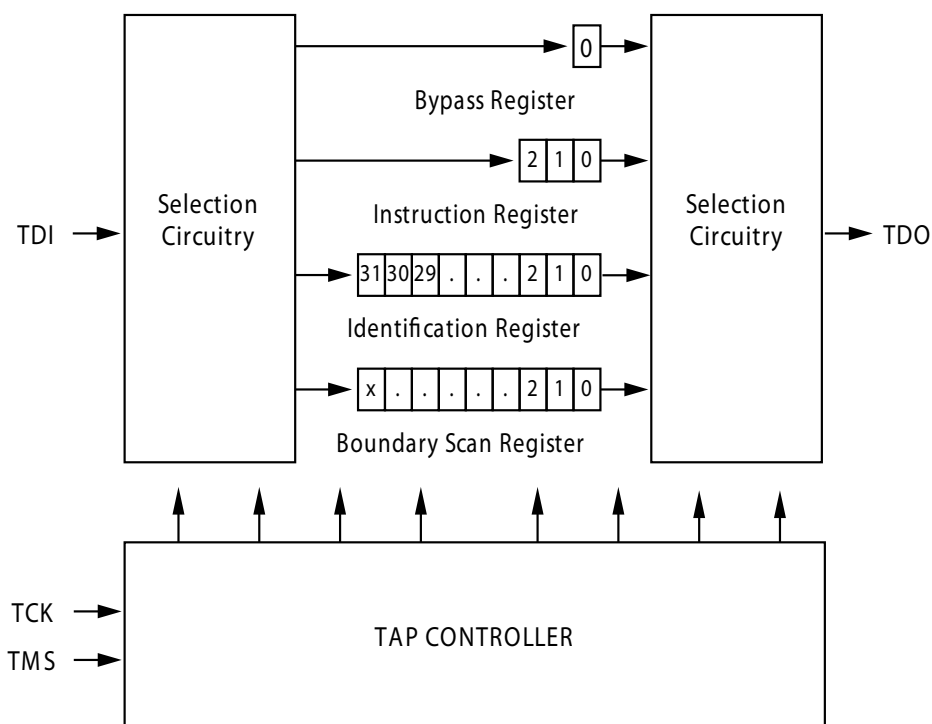
## TAP Controller State Diagram



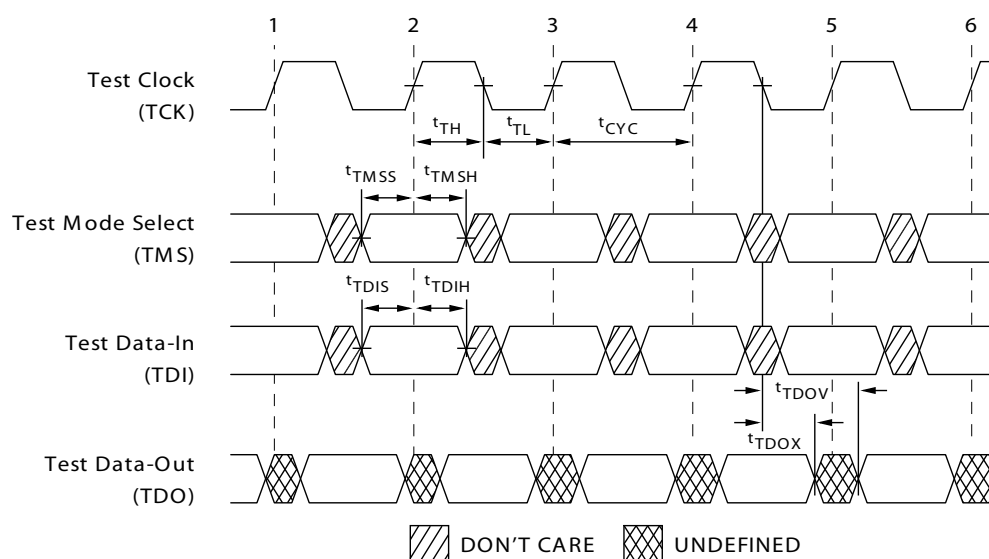
The 0/1 next to each state represents the value of TMS at the rising edge of TCK.



## TAP Controller Block Diagram



## TAP Timing



## TAP AC Switching Characteristics

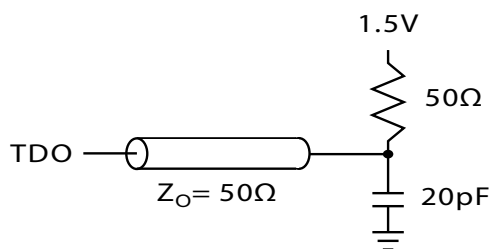
Over the Operating Range

| Parameter <sup>[12, 13]</sup> | Parameter                     | Min | Max | Unit |
|-------------------------------|-------------------------------|-----|-----|------|
| <b>Clock</b>                  |                               |     |     |      |
| $t_{TCYC}$                    | TCK clock cycle time          | 50  | –   | ns   |
| $t_{TF}$                      | TCK clock frequency           | –   | 20  | MHz  |
| $t_{TH}$                      | TCK clock HIGH time           | 20  | –   | ns   |
| $t_{TL}$                      | TCK clock LOW time            | 20  | –   | ns   |
| <b>Output Times</b>           |                               |     |     |      |
| $t_{TDOV}$                    | TCK clock LOW to TDO valid    | –   | 10  | ns   |
| $t_{TDOX}$                    | TCK clock LOW to TDO invalid  | 0   | –   | ns   |
| <b>Set-up Times</b>           |                               |     |     |      |
| $t_{TMSS}$                    | TMS setup to TCK clock rise   | 5   | –   | ns   |
| $t_{TDIS}$                    | TDI setup to TCK clock rise   | 5   | –   | ns   |
| $t_{CS}$                      | Capture setup to TCK rise     | 5   | –   | ns   |
| <b>Hold Times</b>             |                               |     |     |      |
| $t_{TMSH}$                    | TMS hold after TCK clock rise | 5   | –   | ns   |
| $t_{TDIH}$                    | TDI hold after clock rise     | 5   | –   | ns   |
| $t_{CH}$                      | Capture hold after clock rise | 5   | –   | ns   |

### 3.3 V TAP AC Test Conditions

Input pulse levels .....  $V_{SS}$  to 3.3 V  
 Input rise and fall times ..... 1 ns  
 Input timing reference levels ..... 1.5 V  
 Output reference levels ..... 1.5 V  
 Test load termination supply voltage ..... 1.5 V

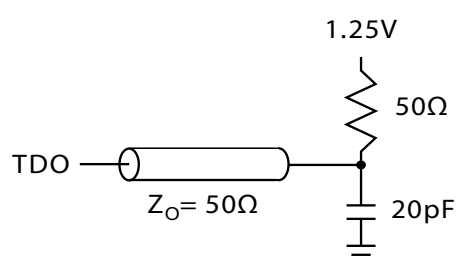
### 3.3 V TAP AC Output Load Equivalent



### 2.5 V TAP AC Test Conditions

Input pulse levels .....  $V_{SS}$  to 2.5 V  
 Input rise and fall time ..... 1 ns  
 Input timing reference levels ..... 1.25 V  
 Output reference levels ..... 1.25 V  
 Test load termination supply voltage ..... 1.25 V

### 2.5 V TAP AC Output Load Equivalent



#### Notes

12.  $t_{CS}$  and  $t_{CH}$  refer to the setup and hold time requirements of latching data from the boundary scan register.  
 13. Test conditions are specified using the load in TAP AC test conditions.  $t_R/t_F = 1$  ns.

## TAP DC Electrical Characteristics and Operating Conditions

(0 °C < T<sub>A</sub> < +70 °C; V<sub>DD</sub> = 3.3 V ± 0.165 V unless otherwise noted)

| Parameter <sup>[14]</sup> | Description         | Test Conditions                          |                          | Min  | Max                   | Unit |
|---------------------------|---------------------|------------------------------------------|--------------------------|------|-----------------------|------|
| V <sub>OH1</sub>          | Output HIGH voltage | I <sub>OH</sub> = -4.0 mA                | V <sub>DDQ</sub> = 3.3 V | 2.4  | –                     | V    |
|                           |                     | I <sub>OH</sub> = -1.0 mA                | V <sub>DDQ</sub> = 2.5 V | 2.0  | –                     | V    |
| V <sub>OH2</sub>          | Output HIGH voltage | I <sub>OH</sub> = -100 µA                | V <sub>DDQ</sub> = 3.3 V | 2.9  | –                     | V    |
|                           |                     |                                          | V <sub>DDQ</sub> = 2.5 V | 2.1  | –                     | V    |
| V <sub>OL1</sub>          | Output LOW voltage  | I <sub>OL</sub> = 8.0 mA                 | V <sub>DDQ</sub> = 3.3 V | –    | 0.4                   | V    |
|                           |                     | I <sub>OL</sub> = 8.0 mA                 | V <sub>DDQ</sub> = 2.5 V | –    | 0.4                   | V    |
| V <sub>OL2</sub>          | Output LOW voltage  | I <sub>OL</sub> = 100 µA                 | V <sub>DDQ</sub> = 3.3 V | –    | 0.2                   | V    |
|                           |                     |                                          | V <sub>DDQ</sub> = 2.5 V | –    | 0.2                   | V    |
| V <sub>IH</sub>           | Input HIGH voltage  |                                          | V <sub>DDQ</sub> = 3.3 V | 2.0  | V <sub>DD</sub> + 0.3 | V    |
|                           |                     |                                          | V <sub>DDQ</sub> = 2.5 V | 1.7  | V <sub>DD</sub> + 0.3 | V    |
| V <sub>IL</sub>           | Input LOW voltage   |                                          | V <sub>DDQ</sub> = 3.3 V | -0.5 | 0.7                   | V    |
|                           |                     |                                          | V <sub>DDQ</sub> = 2.5 V | -0.3 | 0.7                   | V    |
| I <sub>X</sub>            | Input load current  | GND ≤ V <sub>IN</sub> ≤ V <sub>DDQ</sub> |                          | -5   | 5                     | µA   |

### Note

14. All voltages referenced to V<sub>SS</sub> (GND).

## Identification Register Definitions

| Instruction Field                    | CY7C1361C<br>(256K × 36) | Description                                  |
|--------------------------------------|--------------------------|----------------------------------------------|
| Revision number (31:29)              | 000                      | Describes the version number.                |
| Device depth (28:24) <sup>[15]</sup> | 01011                    | Reserved for Internal Use                    |
| Device width (23:18) 119-ball BGA    | 101001                   | Defines memory type and architecture         |
| Cypress device ID (17:12)            | 100110                   | Defines width and density                    |
| Cypress JEDEC ID Code (11:1)         | 00000110100              | Allows unique identification of SRAM vendor. |
| ID register presence indicator (0)   | 1                        | Indicates the presence of an ID register.    |

## Scan Register Sizes

| Register Name                              | Bit Size (× 36) |
|--------------------------------------------|-----------------|
| Instruction                                | 3               |
| Bypass                                     | 1               |
| ID                                         | 32              |
| Boundary scan order (119-ball BGA package) | 71              |

## Instruction Codes

| Instruction    | Code | Description                                                                                                                                |
|----------------|------|--------------------------------------------------------------------------------------------------------------------------------------------|
| EXTEST         | 000  | Captures I/O ring contents. Places the boundary scan register between TDI and TDO. Forces all SRAM outputs to high Z state.                |
| IDCODE         | 001  | Loads the ID register with the vendor ID code and places the register between TDI and TDO. This operation does not affect SRAM operations. |
| SAMPLE Z       | 010  | Captures I/O ring contents. Places the boundary scan register between TDI and TDO. Forces all SRAM output drivers to a high Z state.       |
| RESERVED       | 011  | Do Not Use: This instruction is reserved for future use.                                                                                   |
| SAMPLE/PRELOAD | 100  | Captures I/O ring contents. Places the boundary scan register between TDI and TDO. Does not affect SRAM operation.                         |
| RESERVED       | 101  | Do Not Use: This instruction is reserved for future use.                                                                                   |
| RESERVED       | 110  | Do Not Use: This instruction is reserved for future use.                                                                                   |
| BYPASS         | 111  | Places the bypass register between TDI and TDO. This operation does not affect SRAM operations.                                            |

### Note

<sup>15</sup> Bit #24 is "1" in the Register Definitions for both 2.5 V and 3.3 V versions of this device.

## Boundary Scan Order

119-ball BGA

**CY7C1361C (256K × 36)**

| Bit # | Ball ID | Signal Name       |
|-------|---------|-------------------|
| 1     | K4      | CLK               |
| 2     | H4      | $\overline{GW}$   |
| 3     | M4      | $\overline{BWE}$  |
| 4     | F4      | $\overline{OE}$   |
| 5     | B4      | $\overline{ADSC}$ |
| 6     | A4      | $\overline{ADSP}$ |
| 7     | G4      | ADV               |
| 8     | C3      | A                 |
| 9     | B3      | A                 |
| 10    | D6      | DQP <sub>B</sub>  |
| 11    | H7      | DQ <sub>B</sub>   |
| 12    | G6      | DQ <sub>B</sub>   |
| 13    | E6      | DQ <sub>B</sub>   |
| 14    | D7      | DQ <sub>B</sub>   |
| 15    | E7      | DQ <sub>B</sub>   |
| 16    | F6      | DQ <sub>B</sub>   |
| 17    | G7      | DQ <sub>B</sub>   |
| 18    | H6      | DQ <sub>B</sub>   |
| 19    | T7      | ZZ                |
| 20    | K7      | DQ <sub>A</sub>   |
| 21    | L6      | DQ <sub>A</sub>   |
| 22    | N6      | DQ <sub>A</sub>   |
| 23    | P7      | DQ <sub>A</sub>   |
| 24    | N7      | DQ <sub>A</sub>   |
| 25    | M6      | DQ <sub>A</sub>   |
| 26    | L7      | DQ <sub>A</sub>   |
| 27    | K6      | DQ <sub>A</sub>   |
| 28    | P6      | DQP <sub>A</sub>  |
| 29    | T4      | A                 |
| 30    | A3      | A                 |
| 31    | C5      | A                 |
| 32    | B5      | A                 |
| 33    | A5      | A                 |
| 34    | C6      | A                 |
| 35    | A6      | A                 |
| 36    | B6      | A                 |

| Bit # | Ball ID  | Signal Name       |
|-------|----------|-------------------|
| 37    | P4       | A0                |
| 38    | N4       | A1                |
| 39    | R6       | A                 |
| 40    | T5       | A                 |
| 41    | T3       | A                 |
| 42    | R2       | A                 |
| 43    | R3       | MODE              |
| 44    | P2       | DQP <sub>D</sub>  |
| 45    | P1       | DQ <sub>D</sub>   |
| 46    | L2       | DQ <sub>D</sub>   |
| 47    | K1       | DQ <sub>D</sub>   |
| 48    | N2       | DQ <sub>D</sub>   |
| 49    | N1       | DQ <sub>D</sub>   |
| 50    | M2       | DQ <sub>D</sub>   |
| 51    | L1       | DQ <sub>D</sub>   |
| 52    | K2       | DQ <sub>D</sub>   |
| 53    | Internal | Internal          |
| 54    | H1       | DQ <sub>C</sub>   |
| 55    | G2       | DQ <sub>C</sub>   |
| 56    | E2       | DQ <sub>C</sub>   |
| 57    | D1       | DQ <sub>C</sub>   |
| 58    | H2       | DQ <sub>C</sub>   |
| 59    | G1       | DQ <sub>C</sub>   |
| 60    | F2       | DQ <sub>C</sub>   |
| 61    | E1       | DQ <sub>C</sub>   |
| 62    | D2       | DQP <sub>C</sub>  |
| 63    | C2       | A                 |
| 64    | A2       | A                 |
| 65    | E4       | $\overline{CE}_1$ |
| 66    | B2       | $\overline{CE}_2$ |
| 67    | L3       | BWD               |
| 68    | G3       | $\overline{BW}_C$ |
| 69    | G5       | $\overline{BW}_B$ |
| 70    | L5       | $\overline{BW}_A$ |
| 71    | Internal | Internal          |

## Boundary Scan Order

165-ball FBGA

**CY7C1361C (256K × 36)**

| Bit # | ball ID | Signal Name       |
|-------|---------|-------------------|
| 1     | B6      | CLK               |
| 2     | B7      | $\overline{GW}$   |
| 3     | A7      | $\overline{BWE}$  |
| 4     | B8      | $\overline{OE}$   |
| 5     | A8      | $\overline{ADSC}$ |
| 6     | B9      | $\overline{ADSP}$ |
| 7     | A9      | $\overline{ADV}$  |
| 8     | B10     | A                 |
| 9     | A10     | A                 |
| 10    | C11     | DQP <sub>B</sub>  |
| 11    | E10     | DQ <sub>B</sub>   |
| 12    | F10     | DQ <sub>B</sub>   |
| 13    | G10     | DQ <sub>B</sub>   |
| 14    | D10     | DQ <sub>B</sub>   |
| 15    | D11     | DQ <sub>B</sub>   |
| 16    | E11     | DQ <sub>B</sub>   |
| 17    | F11     | DQ <sub>B</sub>   |
| 18    | G11     | DQ <sub>B</sub>   |
| 19    | H11     | ZZ                |
| 20    | J10     | DQ <sub>A</sub>   |
| 21    | K10     | DQ <sub>A</sub>   |
| 22    | L10     | DQ <sub>A</sub>   |
| 23    | M10     | DQ <sub>A</sub>   |
| 24    | J11     | DQ <sub>A</sub>   |
| 25    | K11     | DQ <sub>A</sub>   |
| 26    | L11     | DQ <sub>A</sub>   |
| 27    | M11     | DQ <sub>A</sub>   |
| 28    | N11     | DQP <sub>A</sub>  |
| 29    | R11     | A                 |
| 30    | R10     | A                 |
| 31    | P10     | A                 |
| 32    | R9      | A                 |
| 33    | P9      | A                 |
| 34    | R8      | A                 |
| 35    | P8      | A                 |
| 36    | P11     | A                 |

| Bit # | ball ID  | Signal Name       |
|-------|----------|-------------------|
| 37    | R6       | A0                |
| 38    | P6       | A1                |
| 39    | R4       | A                 |
| 40    | P4       | A                 |
| 41    | R3       | A                 |
| 42    | P3       | A                 |
| 43    | R1       | MODE              |
| 44    | N1       | DQP <sub>D</sub>  |
| 45    | L2       | DQ <sub>D</sub>   |
| 46    | K2       | DQ <sub>D</sub>   |
| 47    | J2       | DQ <sub>D</sub>   |
| 48    | M2       | DQ <sub>D</sub>   |
| 49    | M1       | DQ <sub>D</sub>   |
| 50    | L1       | DQ <sub>D</sub>   |
| 51    | K1       | DQ <sub>D</sub>   |
| 52    | J1       | DQ <sub>D</sub>   |
| 53    | Internal | Internal          |
| 54    | G2       | DQ <sub>C</sub>   |
| 55    | F2       | DQ <sub>C</sub>   |
| 56    | E2       | DQ <sub>C</sub>   |
| 57    | D2       | DQ <sub>C</sub>   |
| 58    | G1       | DQ <sub>C</sub>   |
| 59    | F1       | DQ <sub>C</sub>   |
| 60    | E1       | DQ <sub>C</sub>   |
| 61    | D1       | DQ <sub>C</sub>   |
| 62    | C1       | DQP <sub>C</sub>  |
| 63    | B2       | A                 |
| 64    | A2       | A                 |
| 65    | A3       | CE <sub>1</sub>   |
| 66    | B3       | CE <sub>2</sub>   |
| 67    | B4       | $\overline{BW}_D$ |
| 68    | A4       | $\overline{BW}_C$ |
| 69    | A5       | $\overline{BW}_B$ |
| 70    | B5       | $\overline{BW}_A$ |
| 71    | A6       | CE <sub>3</sub>   |

## Maximum Ratings

Exceeding maximum ratings may impair the useful life of the device. These user guidelines are not tested.

Storage temperature ..... -65 °C to + 150 °C

Ambient temperature with power applied ..... -55 °C to + 125 °C

Supply voltage on  $V_{DD}$  relative to GND ..... -0.5 V to + 4.6 V

Supply voltage on  $V_{DDQ}$  relative to GND ..... -0.5 V to +  $V_{DD}$

DC voltage applied to outputs in tri-state ..... -0.5 V to  $V_{DDQ} + 0.5$  V

DC input voltage ..... -0.5 V to  $V_{DD} + 0.5$  V

Current into outputs (LOW) ..... 20 mA

Static discharge voltage (per MIL-STD-883, method 3015) ..... > 2001 V

Latch-up current ..... > 200 mA

## Operating Range

| Range      | Ambient Temperature | $V_{DD}$           | $V_{DDQ}$              |
|------------|---------------------|--------------------|------------------------|
| Commercial | 0 °C to +70 °C      | 3.3 V – 5% / + 10% | 2.5 V – 5% to $V_{DD}$ |
| Industrial | -40 °C to +85 °C    |                    |                        |
| Automotive | -40 °C to +125 °C   |                    |                        |

## Neutron Soft Error Immunity

| Parameter | Description               | Test Conditions | Typ | Max* | Unit    |
|-----------|---------------------------|-----------------|-----|------|---------|
| LSBU      | Logical single-bit upsets | 25 °C           | 361 | 394  | FIT/Mb  |
| LMBU      | Logical multi-bit upsets  | 25 °C           | 0   | 0.01 | FIT/Mb  |
| SEL       | Single event latch up     | 85 °C           | 0   | 0.1  | FIT/Dev |

\* No LMBU or SEL events occurred during testing; this column represents a statistical  $\chi^2$ , 95% confidence limit calculation. For more details refer to Application Note AN54908 "Accelerated Neutron SER Testing and Calculation of Terrestrial Failure Rates"

## Electrical Characteristics

Over the Operating Range

| Parameter <sup>[16, 17]</sup> | Description                              | Test Conditions                               | Min   | Max              | Unit    |
|-------------------------------|------------------------------------------|-----------------------------------------------|-------|------------------|---------|
| $V_{DD}$                      | Power supply voltage                     |                                               | 3.135 | 3.6              | V       |
| $V_{DDQ}$                     | I/O supply voltage                       | for 3.3 V I/O                                 | 3.135 | $V_{DD}$         | V       |
|                               |                                          | for 2.5 V I/O                                 | 2.375 | 2.625            | V       |
| $V_{OH}$                      | Output HIGH voltage                      | for 3.3 V I/O, $I_{OH} = -4.0$ mA             | 2.4   | –                | V       |
|                               |                                          | for 2.5 V I/O, $I_{OH} = -1.0$ mA             | 2.0   | –                | V       |
| $V_{OL}$                      | Output LOW voltage                       | for 3.3 V I/O, $I_{OL} = 8.0$ mA              | –     | 0.4              | V       |
|                               |                                          | for 2.5 V I/O, $I_{OL} = 1.0$ mA              | –     | 0.4              | V       |
| $V_{IH}$                      | Input HIGH voltage <sup>[16]</sup>       | for 3.3 V I/O                                 | 2.0   | $V_{DD} + 0.3$ V | V       |
|                               |                                          | for 2.5 V I/O                                 | 1.7   | $V_{DD} + 0.3$ V | V       |
| $V_{IL}$                      | Input LOW voltage <sup>[16]</sup>        | for 3.3 V I/O                                 | -0.3  | 0.8              | V       |
|                               |                                          | for 2.5 V I/O                                 | -0.3  | 0.7              | V       |
| $I_X$                         | Input leakage current except ZZ and MODE | $GND \leq V_I \leq V_{DDQ}$                   | -5    | 5                | $\mu$ A |
|                               | Input current of MODE                    | Input = $V_{SS}$                              | -30   | –                | $\mu$ A |
|                               |                                          | Input = $V_{DD}$                              | –     | 5                | $\mu$ A |
|                               | Input current of ZZ                      | Input = $V_{SS}$                              | -5    | –                | $\mu$ A |
|                               |                                          | Input = $V_{DD}$                              | –     | 30               | $\mu$ A |
| $I_{OZ}$                      | Output leakage current                   | $GND \leq V_I \leq V_{DDQ}$ , output disabled | -5    | 5                | $\mu$ A |

### Notes

16. Overshoot:  $V_{IH(AC)} < V_{DD} + 1.5$  V (Pulse width less than  $t_{CYC}/2$ ), undershoot:  $V_{IL(AC)} > -2$  V (Pulse width less than  $t_{CYC}/2$ ).

17.  $T_{Power-up}$ : Assumes a linear ramp from 0 V to  $V_{DD(min)}$  within 200 ms. During this time  $V_{IH} < V_{DD}$  and  $V_{DDQ} \leq V_{DD}$ .

## Electrical Characteristics *(continued)*

Over the Operating Range

| Parameter <sup>[16, 17]</sup> | Description                                      | Test Conditions                                                                                                                                 |                                           | Min | Max | Unit |
|-------------------------------|--------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------|-----|-----|------|
| $I_{DD}$                      | $V_{DD}$ operating supply current                | $V_{DD} = \text{Max}$ , $I_{OUT} = 0 \text{ mA}$ ,<br>$f = f_{MAX} = 1/t_{CYC}$                                                                 | 7.5 ns cycle,<br>133 MHz                  | –   | 250 | mA   |
|                               |                                                  |                                                                                                                                                 | 10 ns cycle,<br>100 MHz                   | –   | 180 |      |
| $I_{SB1}$                     | Automatic CE power-down<br>current – TTL inputs  | Max $V_{DD}$ , device deselected,<br>$V_{IN} \geq V_{IH}$ or $V_{IN} \leq V_{IL}$ , $f = f_{MAX}$ ,<br>inputs switching                         | All speeds<br>(Commercial<br>/Industrial) | –   | 110 | mA   |
|                               |                                                  |                                                                                                                                                 | 10 ns cycle,<br>100 MHz<br>(Automotive)   | –   | 150 | mA   |
| $I_{SB2}$                     | Automatic CE power-down<br>current – CMOS inputs | Max $V_{DD}$ , device deselected,<br>$V_{IN} \geq V_{DD} - 0.3 \text{ V}$ or $V_{IN} \leq 0.3 \text{ V}$ ,<br>$f = 0$ , inputs static           | All speeds                                | –   | 40  | mA   |
| $I_{SB3}$                     | Automatic CE power-down<br>current – CMOS inputs | Max $V_{DD}$ , device deselected,<br>$V_{IN} \geq V_{DDQ} - 0.3 \text{ V}$ or $V_{IN} \leq 0.3 \text{ V}$ ,<br>$f = f_{MAX}$ , inputs switching | All speeds<br>(Commercial<br>/Industrial) | –   | 100 | mA   |
|                               |                                                  |                                                                                                                                                 | 10 ns cycle,<br>100 MHz<br>(Automotive)   | –   | 120 | mA   |
| $I_{SB4}$                     | Automatic CE power-down<br>current – TTL inputs  | Max $V_{DD}$ , device deselected,<br>$V_{IN} \geq V_{IH}$ or $V_{IN} \leq V_{IL}$ ,<br>$f = 0$ , inputs static                                  | All speeds<br>(Commercial<br>/Industrial) | –   | 40  | mA   |
|                               |                                                  |                                                                                                                                                 | 10 ns cycle,<br>100 MHz<br>(Automotive)   | –   | 60  | mA   |

## Capacitance

| Parameter <sup>[18]</sup> | Description              | Test Conditions                                                                                             | 100-pin TQFP<br>Max | 119-ball BGA<br>Max | 165-ball FBGA<br>Max | Unit |
|---------------------------|--------------------------|-------------------------------------------------------------------------------------------------------------|---------------------|---------------------|----------------------|------|
| $C_{IN}$                  | Input capacitance        | $T_A = 25^\circ\text{C}$ , $f = 1 \text{ MHz}$ ,<br>$V_{DD} = 3.3 \text{ V}$ ,<br>$V_{DDQ} = 2.5 \text{ V}$ | 5                   | 5                   | 5                    | pF   |
| $C_{CLK}$                 | Clock input capacitance  |                                                                                                             | 5                   | 5                   | 5                    | pF   |
| $C_{I/O}$                 | Input/output capacitance |                                                                                                             | 5                   | 7                   | 7                    | pF   |

## Thermal Resistance

| Parameter <sup>[18]</sup> | Description                                 | Test Conditions                                                                                                                     | 100-pin TQFP<br>Package | 119-ball BGA<br>Package | 165-ball FBGA<br>Package | Unit               |
|---------------------------|---------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------|-------------------------|-------------------------|--------------------------|--------------------|
| $\Theta_{JA}$             | Thermal resistance<br>(junction to ambient) | Test conditions follow<br>standard test methods<br>and procedures for<br>measuring thermal<br>impedance, according<br>to EIA/JESD51 | 29.41                   | 34.1                    | 16.8                     | $^\circ\text{C/W}$ |
| $\Theta_{JC}$             | Thermal resistance<br>(junction to case)    |                                                                                                                                     | 6.31                    | 14.0                    | 3.0                      | $^\circ\text{C/W}$ |

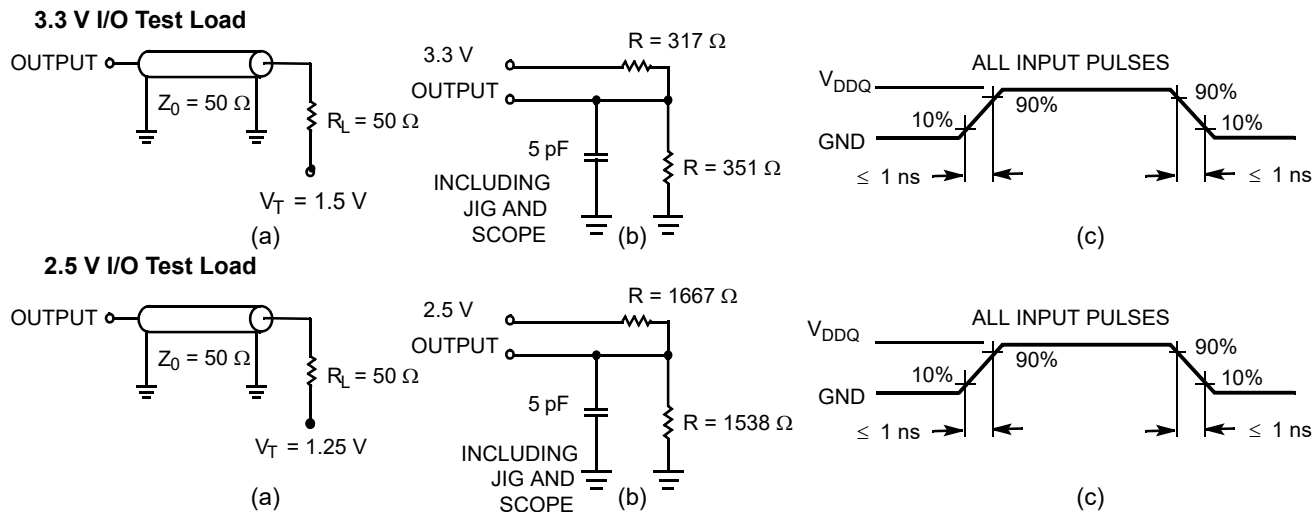
### Note

18. Tested initially and after any design or process change that may affect these parameters.



## AC Test Loads and Waveforms

Figure 5. AC Test Loads and Waveforms



## Switching Characteristics

Over the Operating Range

| Parameter <sup>[19, 20]</sup> | Description                                                          | -133 |     | -100 |     | Unit |
|-------------------------------|----------------------------------------------------------------------|------|-----|------|-----|------|
|                               |                                                                      | Min  | Max | Min  | Max |      |
| t <sub>POWER</sub>            | V <sub>DD</sub> (typical) to the first access <sup>[21]</sup>        | 1    | –   | 1    | –   | ms   |
| <b>Clock</b>                  |                                                                      |      |     |      |     |      |
| t <sub>CYC</sub>              | Clock cycle time                                                     | 7.5  | –   | 10   | –   | ns   |
| t <sub>CH</sub>               | Clock HIGH                                                           | 3.0  | –   | 4.0  | –   | ns   |
| t <sub>CL</sub>               | Clock LOW                                                            | 3.0  | –   | 4.0  | –   | ns   |
| <b>Output Times</b>           |                                                                      |      |     |      |     |      |
| t <sub>CDV</sub>              | Data output valid after CLK rise                                     | –    | 6.5 | –    | 8.5 | ns   |
| t <sub>DOH</sub>              | Data output hold after CLK rise                                      | 2.0  | –   | 2.0  | –   | ns   |
| t <sub>CLZ</sub>              | Clock to low Z <sup>[22, 23, 24]</sup>                               | 0    | –   | 0    | –   | ns   |
| t <sub>CHZ</sub>              | Clock to high Z <sup>[22, 23, 24]</sup>                              | –    | 3.5 | –    | 3.5 | ns   |
| t <sub>OE<sub>V</sub></sub>   | $\overline{\text{OE}}$ LOW to output valid                           | –    | 3.5 | –    | 3.5 | ns   |
| t <sub>OE<sub>LZ</sub></sub>  | $\overline{\text{OE}}$ LOW to output low Z <sup>[22, 23, 24]</sup>   | 0    | –   | 0    | –   | ns   |
| t <sub>OE<sub>HZ</sub></sub>  | $\overline{\text{OE}}$ HIGH to output high Z <sup>[22, 23, 24]</sup> | –    | 3.5 | –    | 3.5 | ns   |
| <b>Set-up Times</b>           |                                                                      |      |     |      |     |      |
| t <sub>AS</sub>               | Address setup before CLK rise                                        | 1.5  | –   | 1.5  | –   | ns   |
| t <sub>ADS</sub>              | ADSP, ADSC setup before CLK rise                                     | 1.5  | –   | 1.5  | –   | ns   |
| t <sub>ADVS</sub>             | ADV setup before CLK rise                                            | 1.5  | –   | 1.5  | –   | ns   |
| t <sub>WES</sub>              | GW, BWE, BW <sub>[A:D]</sub> setup before CLK rise                   | 1.5  | –   | 1.5  | –   | ns   |
| t <sub>DS</sub>               | Data input setup before CLK rise                                     | 1.5  | –   | 1.5  | –   | ns   |
| t <sub>CES</sub>              | Chip enable setup                                                    | 1.5  | –   | 1.5  | –   | ns   |
| <b>Hold Times</b>             |                                                                      |      |     |      |     |      |
| t <sub>AH</sub>               | Address hold after CLK rise                                          | 0.5  | –   | 0.5  | –   | ns   |
| t <sub>ADH</sub>              | ADSP, ADSC hold after CLK rise                                       | 0.5  | –   | 0.5  | –   | ns   |
| t <sub>WEH</sub>              | GW, BWE, BW <sub>[A:D]</sub> hold after CLK rise                     | 0.5  | –   | 0.5  | –   | ns   |
| t <sub>ADVH</sub>             | ADV hold after CLK rise                                              | 0.5  | –   | 0.5  | –   | ns   |
| t <sub>DH</sub>               | Data input hold after CLK rise                                       | 0.5  | –   | 0.5  | –   | ns   |
| t <sub>CEH</sub>              | Chip enable hold after CLK rise                                      | 0.5  | –   | 0.5  | –   | ns   |

### Notes

19. Timing reference level is 1.5 V when V<sub>DDQ</sub> = 3.3 V and is 1.25 V when V<sub>DDQ</sub> = 2.5 V.

20. Test conditions shown in (a) of [Figure 5 on page 24](#) unless otherwise noted.

21. This part has a voltage regulator internally; t<sub>POWER</sub> is the time that the power needs to be supplied above V<sub>DD(minimum)</sub> initially, before a read or write operation can be initiated.

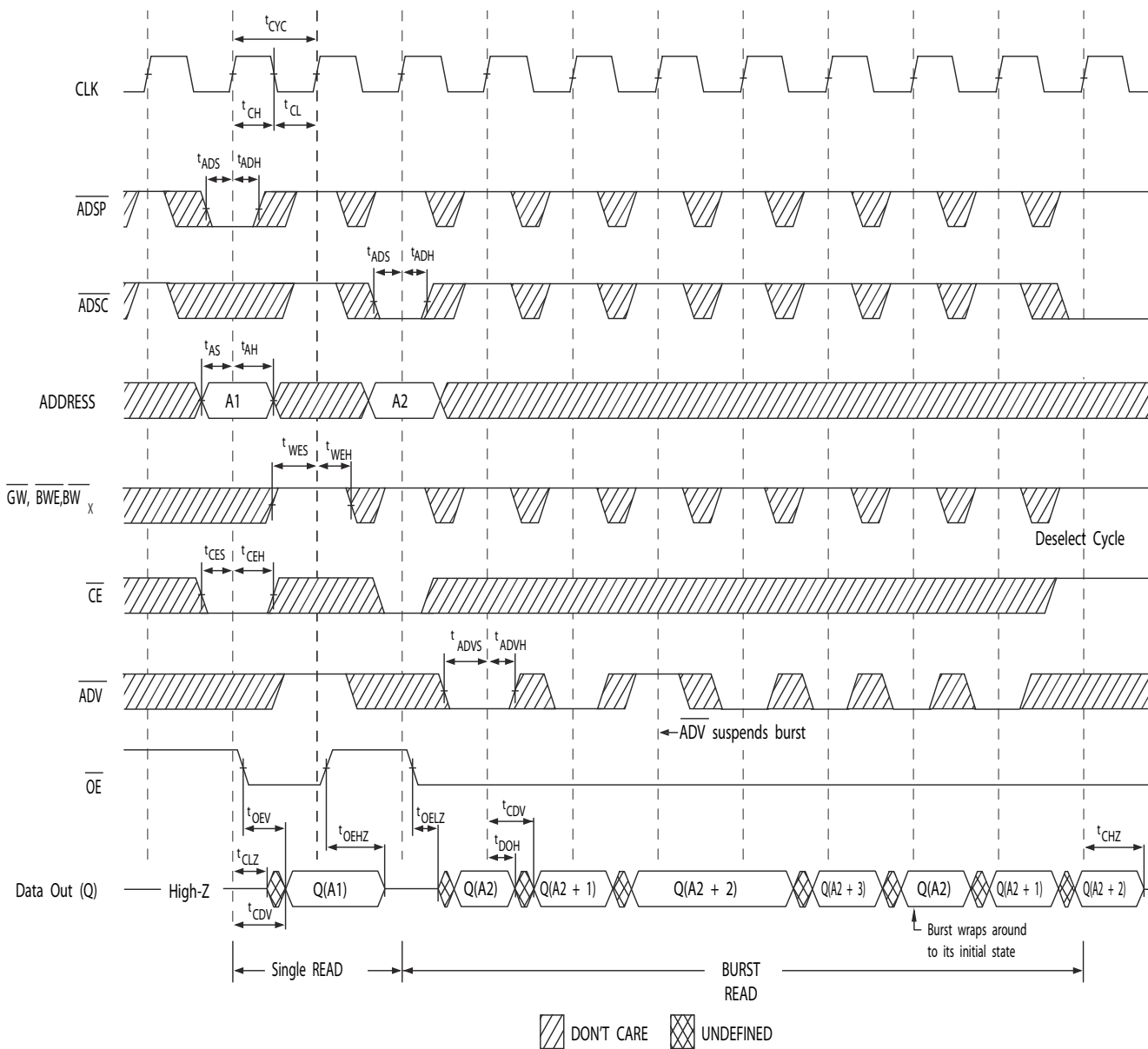
22. t<sub>CHZ</sub>, t<sub>CLZ</sub>, t<sub>OE<sub>LZ</sub></sub>, and t<sub>OE<sub>HZ</sub></sub> are specified with AC test conditions shown in part (b) of [Figure 5 on page 24](#). Transition is measured ± 200 mV from steady-state voltage.

23. At any given voltage and temperature, t<sub>OE<sub>HZ</sub></sub> is less than t<sub>OE<sub>LZ</sub></sub> and t<sub>CHZ</sub> is less than t<sub>CLZ</sub> to eliminate bus contention between SRAMs when sharing the same data bus. These specifications do not imply a bus contention condition, but reflect parameters guaranteed over worst case user conditions. Device is designed to achieve high Z prior to low Z under the same system conditions.

24. This parameter is sampled and not 100% tested.

## Timing Diagrams

Figure 6. Read Cycle Timing [25]

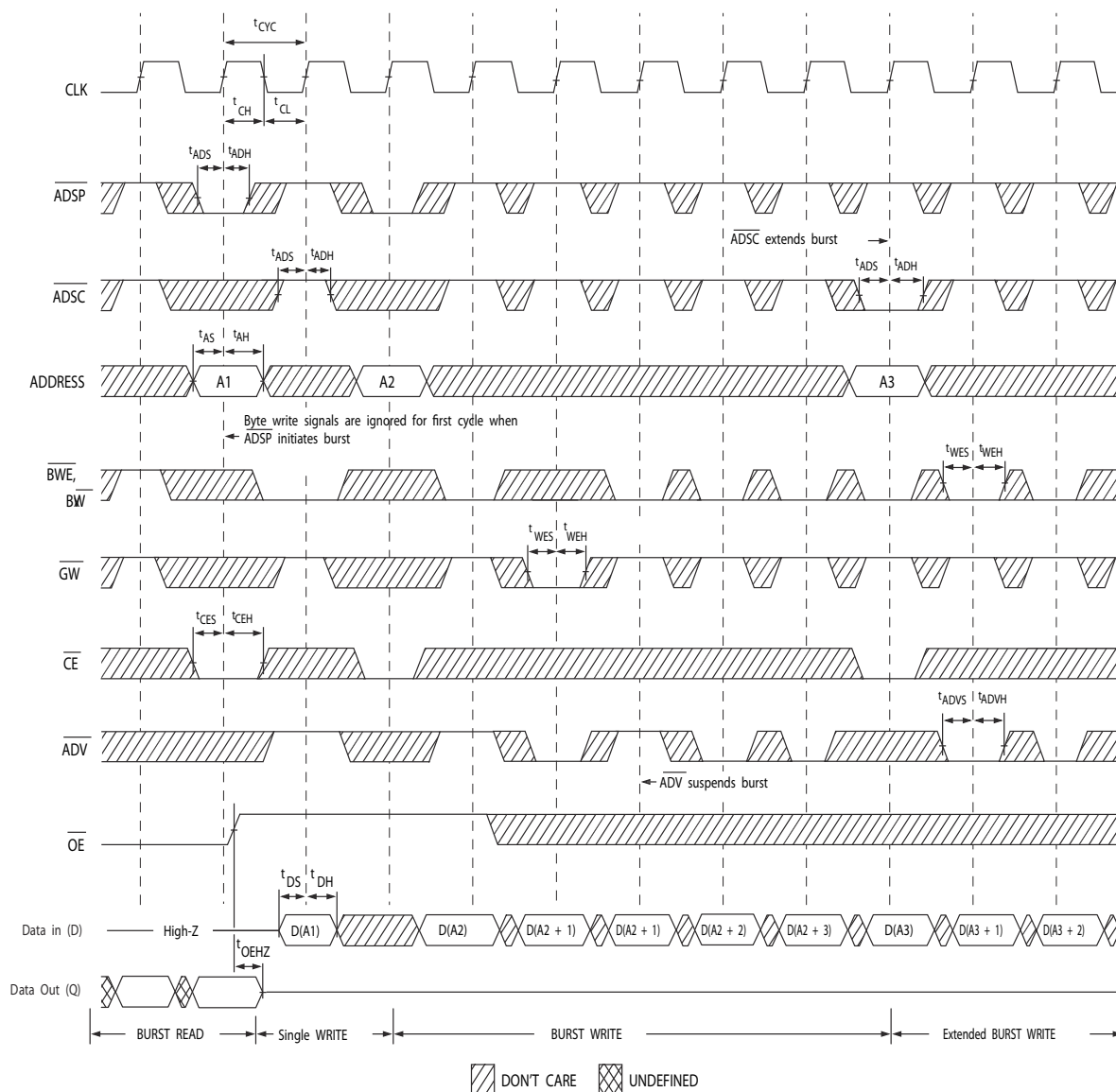


**Note**

25. On this diagram, when  $\overline{CE}$  is LOW:  $\overline{CE}_1$  is LOW,  $CE_2$  is HIGH and  $\overline{CE}_3$  is LOW. When  $\overline{CE}$  is HIGH:  $\overline{CE}_1$  is HIGH or  $CE_2$  is LOW or  $\overline{CE}_3$  is HIGH.

## Timing Diagrams (continued)

Figure 7. Write Cycle Timing [26, 27]



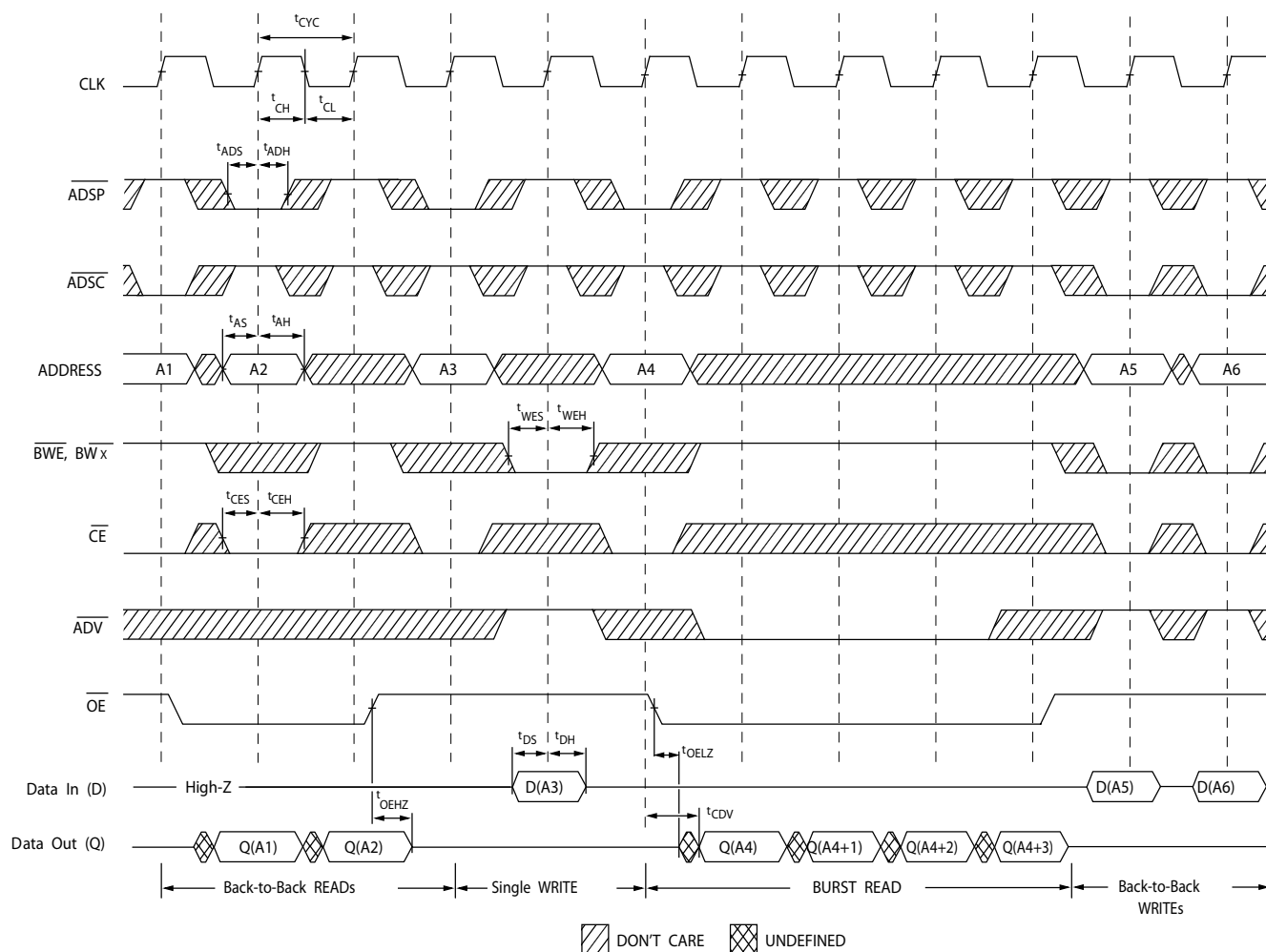
### Notes

26. On this diagram, when  $\overline{CE}$  is LOW:  $\overline{CE}_1$  is LOW,  $\overline{CE}_2$  is HIGH and  $\overline{CE}_3$  is LOW. When  $\overline{CE}$  is HIGH:  $\overline{CE}_1$  is HIGH or  $\overline{CE}_2$  is LOW or  $\overline{CE}_3$  is HIGH.

27. Full width write can be initiated by either  $\overline{GW}$  LOW; or by  $\overline{GW}$  HIGH,  $\overline{BWE}$  LOW and  $\overline{BW}_X$  LOW.

## Timing Diagrams (continued)

Figure 8. Read/Write Cycle Timing [28, 29, 30]

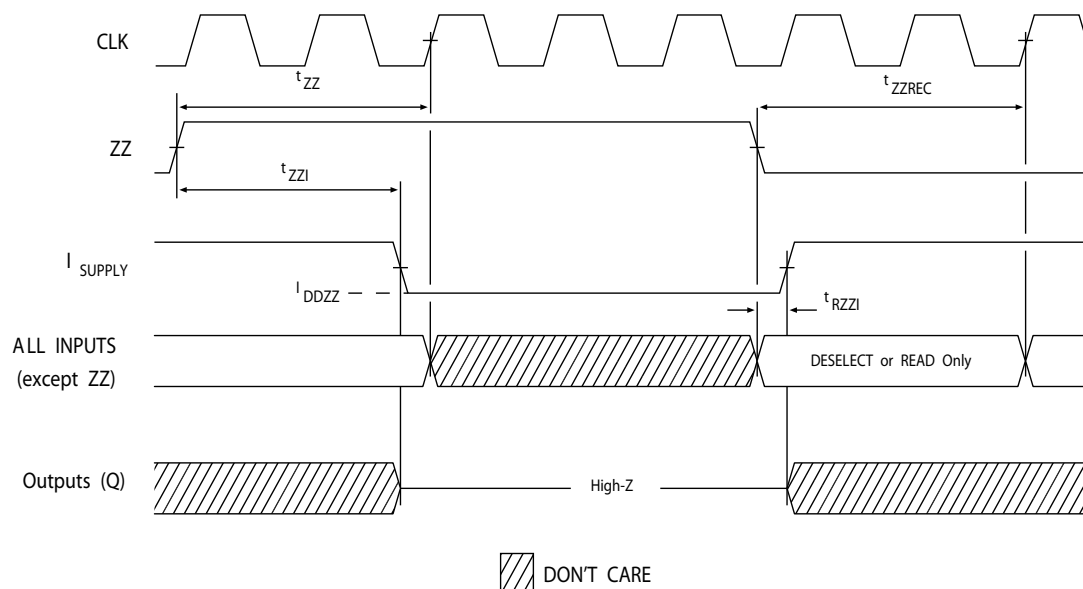


### Notes

28. On this diagram, when  $\overline{CE}$  is LOW:  $\overline{CE}_1$  is LOW,  $\overline{CE}_2$  is HIGH and  $\overline{CE}_3$  is LOW. When  $\overline{CE}$  is HIGH:  $\overline{CE}_1$  is HIGH or  $\overline{CE}_2$  is LOW or  $\overline{CE}_3$  is HIGH.
29. The data bus (Q) remains in high Z following a WRITE cycle, unless a new read access is initiated by ADSP or ADSC.
30.  $\overline{GW}$  is HIGH.

## Timing Diagrams *(continued)*

**Figure 9. ZZ Mode Timing** [31, 32]



### Notes

31. Device must be deselected when entering ZZ mode. See Cycle Descriptions table for all possible signal conditions to deselect the device.  
 32. DQs are in high Z when exiting ZZ sleep mode.

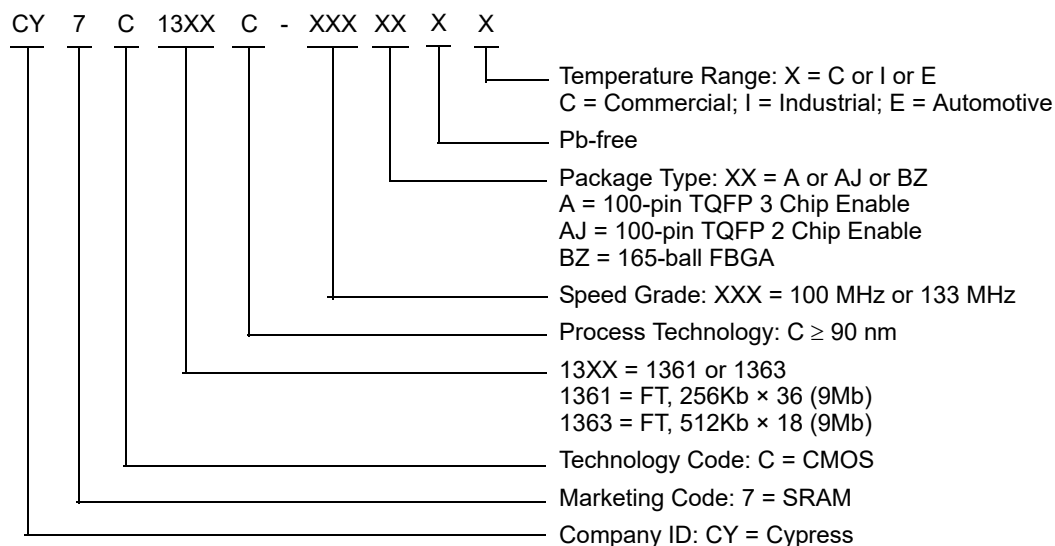
## Ordering Information

The table below contains only the parts that are currently available. If you don't see what you are looking for, please contact your local sales representative. For more information, visit the Cypress website at [www.cypress.com](http://www.cypress.com) and refer to the product summary page at <http://www.cypress.com/products>

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| Speed (MHz) | Ordering Code     | Status     | Package Diagram | Part and Package Type                                    | Operating Range |
|-------------|-------------------|------------|-----------------|----------------------------------------------------------|-----------------|
| 133         | CY7C1361C-133AXC  | Production | 51-85050        | 100-pin TQFP (14 × 20 × 1.4 mm) Pb-free (3 Chip Enable)  | Commercial      |
|             | CY7C1363C-133AXC  | Production |                 |                                                          |                 |
|             | CY7C1361C-133AXI  | Production | 51-85050        | 100-pin TQFP (14 × 20 × 1.4 mm) Pb-free (3 Chip Enable)  | Industrial      |
| 100         | CY7C1361C-100AXC  | Production | 51-85050        | 100-pin TQFP (14 × 20 × 1.4 mm) Pb-free (3 Chip Enable)  | Commercial      |
|             | CY7C1361C-100AXE  | Production | 51-85050        | 100-pin TQFP (14 × 20 × 1.4 mm) Pb-free (3 Chip Enable)  | Automotive      |
|             | CY7C1361C-100BZXE | Production | 51-85180        | 165-ball FBGA (13 × 15 × 1.4 mm) Pb-free (3 Chip Enable) |                 |

## Ordering Code Definitions

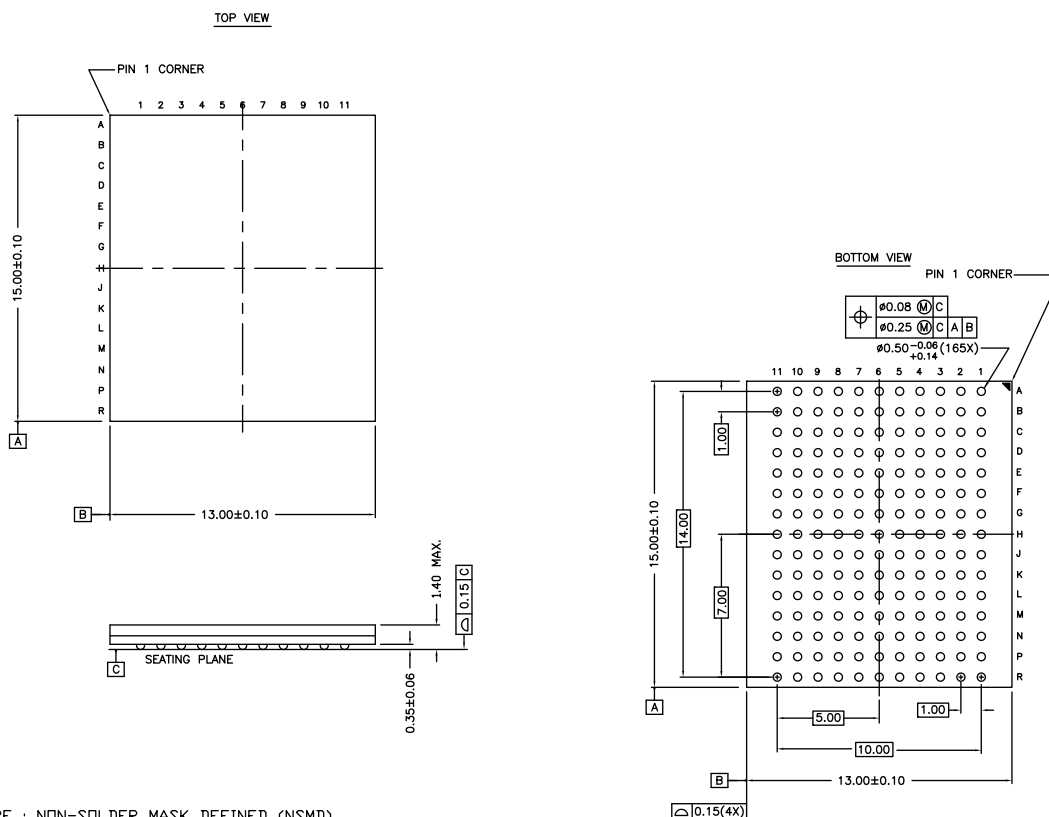






## Package Diagrams (continued)

**Figure 11. 165-ball FBGA ((13 × 15 × 1.4 mm) 0.5 Ball Diameter) Package Outline, 51-85180**



NOTES :

SOLDER PAD TYPE : NON-SOLDER MASK DEFINED (NSMD)

JEDEC REFERENCE : MO-216 / ISSUE E

PACKAGE CODE : BB0AC/BW0AC

PACKAGE WEIGHT : SEE CYPRESS PACKAGE MATERIAL DECLARATION

DATASHEET (PMDD) POSTED ON THE CYPRESS WEB.

51-85180 \*G

## Acronyms

| Acronym | Description                                |
|---------|--------------------------------------------|
| BGA     | Ball Grid Array                            |
| CMOS    | Complementary Metal Oxide Semiconductor    |
| CE      | Chip Enable                                |
| EIA     | Electronic Industries Alliance             |
| FBGA    | Fine-Pitch Ball Grid Array                 |
| I/O     | Input/Output                               |
| JEDEC   | Joint Electron Devices Engineering Council |
| JTAG    | Joint Test Action Group                    |
| LMBU    | Logical Multi-Bit Upsets                   |
| LSB     | Least Significant Bit                      |
| LSBU    | Logical Single-Bit Upsets                  |
| MSB     | Most Significant Bit                       |
| OE      | Output Enable                              |
| PBGA    | Plastic Ball Grid Array                    |
| SEL     | Single Event Latch up                      |
| SRAM    | Static Random Access Memory                |
| TAP     | Test Access Port                           |
| TCK     | Test Clock                                 |
| TDI     | Test Data-In                               |
| TDO     | Test Data-Out                              |
| TMS     | Test Mode Select                           |
| TQFP    | Thin Quad Flat Pack                        |
| TTL     | Transistor-Transistor Logic                |

## Document Conventions

### Units of Measure

| Symbol | Unit of Measure |
|--------|-----------------|
| °C     | degree Celsius  |
| MHz    | megahertz       |
| μA     | microampere     |
| mA     | milliampere     |
| mm     | millimeter      |
| ms     | millisecond     |
| mV     | millivolt       |
| ns     | nanosecond      |
| Ω      | ohm             |
| %      | percent         |
| pF     | picofarad       |
| V      | volt            |
| W      | watt            |

## Document History Page

| Document Title: CY7C1361C/CY7C1363C, 9-Mbit (256K × 36/512K × 18) Flow-Through SRAM<br>Document Number: 38-05541 |         |                 |                 |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
|------------------------------------------------------------------------------------------------------------------|---------|-----------------|-----------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Rev.                                                                                                             | ECN No. | Orig. of Change | Submission Date | Description of Change                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                            |
| **                                                                                                               | 241690  | RKF             | 07/12/2004      | New data sheet.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
| *A                                                                                                               | 278969  | RKF             | 10/18/2004      | Updated <a href="#">Boundary Scan Order</a> (Changed to match the B rev of these devices).<br>Updated Boundary Scan Order (Changed to match the B rev of these devices).                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         |
| *B                                                                                                               | 332059  | PCI             | 03/11/2005      | Updated <a href="#">Features</a> (Removed 117 MHz frequency related information).<br>Updated <a href="#">Selection Guide</a> (Removed 117 MHz frequency related information).<br>Updated <a href="#">Pin Configurations</a> (Address expansion pins/balls in the pinouts for all packages are modified as per JEDEC standard).<br>Updated <a href="#">Pin Definitions</a> (Added Address Expansion pins).<br>Updated <a href="#">Functional Overview</a> (Updated <a href="#">ZZ Mode Electrical Characteristics</a> (Changed maximum value of I <sub>DDZZ</sub> parameter from 35 mA to 50 mA)).<br>Updated <a href="#">Identification Register Definitions</a> (Split Device Width (23:18) into two rows; retained the same values for 165-ball FBGA; Changed Device Width (23:18) for 119-ball BGA from 000001 to 101001).<br>Updated <a href="#">Electrical Characteristics</a> (Updated Test Conditions of V <sub>OH</sub> , V <sub>OL</sub> parameters; changed maximum value of I <sub>SB1</sub> parameter from 40 mA to 110 mA; changed maximum value of I <sub>SB3</sub> parameter from 40 mA to 100 mA respectively; changed Test Condition of I <sub>SB4</sub> parameter from (V <sub>IN</sub> ≥ V <sub>DD</sub> – 0.3 V or V <sub>IN</sub> ≤ 0.3 V) to (V <sub>IN</sub> ≥ V <sub>IH</sub> or V <sub>IN</sub> ≤ V <sub>IL</sub> ); removed 117 MHz frequency related information).<br>Updated <a href="#">Thermal Resistance</a> (Changed value of $\theta_{JA}$ and $\theta_{JC}$ parameters for 100-pin TQFP Package from 25 °C/W and 9 °C/W to 29.41 °C/W and 6.13 °C/W respectively; changed value of $\theta_{JA}$ and $\theta_{JC}$ for 119-ball BGA Package from 25 °C/W and 6 °C/W to 34.1 °C/W and 14.0 °C/W respectively; changed value of $\theta_{JA}$ and $\theta_{JC}$ for 165-ball FBGA Package from 27 °C/W and 6 °C/W to 16.8 °C/W and 3.0 °C/W respectively).<br>Updated <a href="#">Switching Characteristics</a> (Removed 117 MHz frequency related information).<br>Updated <a href="#">Ordering Information</a> (Updated part numbers (Added lead-free information for 100-pin TQFP, 119-ball BGA and 165-ball FBGA packages)). |
| *C                                                                                                               | 377095  | PCI             | 06/10/2005      | Updated <a href="#">Electrical Characteristics</a> (Updated Note 17 (Modified test condition from V <sub>IH</sub> ≤ V <sub>DD</sub> to V <sub>IH</sub> < V <sub>DD</sub> ); changed maximum value of I <sub>SB2</sub> parameter from 30 mA to 40 mA).                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                            |
| *D                                                                                                               | 408298  | R XU            | 11/16/2005      | Changed address of Cypress Semiconductor Corporation from “3901 North First Street” to “198 Champion Court”.<br>Replaced three-state with tri-state in all instances across the document.<br>Updated <a href="#">Electrical Characteristics</a> (Changed “Input Load Current except ZZ and MODE” to “Input Leakage Current except ZZ and MODE” in the description of I <sub>X</sub> parameter).<br>Updated <a href="#">Ordering Information</a> (Updated part numbers; replaced Package Name column with Package Diagram in the Ordering Information table).<br>Updated <a href="#">Package Diagrams</a> :<br>spec 51-85180 – Changed revision from ** to *A.<br>Updated to new template.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
| *E                                                                                                               | 433033  | NXR             | 03/16/2006      | Updated <a href="#">Features</a> (Included Automotive Temperature Range).<br>Updated <a href="#">Selection Guide</a> (Included Automotive Temperature Range).<br>Updated <a href="#">Functional Overview</a> (Updated <a href="#">ZZ Mode Electrical Characteristics</a> (Included Automotive Temperature Range)).<br>Updated <a href="#">Operating Range</a> (Included Automotive Temperature Range).<br>Updated <a href="#">Electrical Characteristics</a> (Included Automotive Temperature Range).<br>Updated <a href="#">Ordering Information</a> (Updated part numbers).<br>Updated <a href="#">Package Diagrams</a> :<br>spec 51-85050 – Changed revision from *A to *B.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |

**Document History Page** (continued)

| Document Title: CY7C1361C/CY7C1363C, 9-Mbit (256K × 36/512K × 18) Flow-Through SRAM<br>Document Number: 38-05541 |         |                 |                 |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |
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| Rev.                                                                                                             | ECN No. | Orig. of Change | Submission Date | Description of Change                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| *F                                                                                                               | 501793  | VKN             | 09/13/2006      | Updated <a href="#">TAP AC Switching Characteristics</a> (Changed minimum value of $t_{TH}$ and $t_{TL}$ parameters from 25 ns to 20 ns; and maximum value of $t_{TDOV}$ parameter from 5 ns to 10 ns).<br>Updated <a href="#">Maximum Ratings</a> (Added the Maximum Rating for Supply Voltage on $V_{DDQ}$ Relative to GND).<br>Updated <a href="#">Ordering Information</a> :<br>Updated part numbers.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |
| *G                                                                                                               | 2756340 | VKN / AESA      | 08/26/2009      | Added <a href="#">Neutron Soft Error Immunity</a> .<br>Updated <a href="#">Ordering Information</a> (Updated part numbers; and modified the disclaimer for the Ordering information).<br>Updated <a href="#">Package Diagrams</a> :<br>spec 51-85180 – Changed revision from *A to *B.<br>Updated to new template.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
| *H                                                                                                               | 3036754 | NJY             | 09/23/2010      | Updated <a href="#">Ordering Information</a> :<br>No change in part numbers.<br>Added <a href="#">Ordering Code Definitions</a> .<br>Updated <a href="#">Package Diagrams</a> :<br>spec 51-85050 – Changed revision from *B to *C.<br>spec 51-85115 – Changed revision from *B to *C.<br>spec 51-85180 – Changed revision from *B to *C.<br>Added <a href="#">Acronyms</a> and <a href="#">Units of Measure</a> .<br>Minor edits.<br>Updated to new template.<br>Completing Sunset Review.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| *I                                                                                                               | 3050869 | NJY             | 10/07/2010      | Updated <a href="#">Ordering Information</a> (Updated part numbers).                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                            |
| *J                                                                                                               | 3096309 | NJY             | 11/28/2010      | Updated <a href="#">Pin Definitions</a> .                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |
| *K                                                                                                               | 3367594 | PRIT            | 09/09/2011      | Updated <a href="#">Package Diagrams</a> :<br>spec 51-85050 – Changed revision from *C to *D.<br>Updated to new template.<br>Completing Sunset Review.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |
| *L                                                                                                               | 3612494 | PRIT            | 05/09/2012      | Updated <a href="#">Functional Description</a> (Removed the Note “For best-practices recommendations, refer to the Cypress application note <i>System Design Guidelines</i> on <a href="http://www.cypress.com">www.cypress.com</a> .” and its reference).<br>Updated <a href="#">Pin Configurations</a> (Removed 165-ball FBGA Package related information; updated <a href="#">Figure 3</a> (Removed CY7C1363C related information)).<br>Updated <a href="#">IEEE 1149.1 Serial Boundary Scan (JTAG)</a> (Removed CY7C1363C related information).<br>Updated <a href="#">Identification Register Definitions</a> (Removed CY7C1363C related information; removed 165-ball FBGA Package related information).<br>Updated <a href="#">Scan Register Sizes</a> (Removed “Bit Size (× 18)” column; removed 165-ball FBGA Package related information).<br>Updated <a href="#">Boundary Scan Order</a> (Removed CY7C1363C related information).<br>Removed Boundary Scan Order (Corresponding to 165-ball FBGA Package).<br>Updated <a href="#">Capacitance</a> (Removed 165-ball FBGA Package related information).<br>Updated <a href="#">Thermal Resistance</a> (Removed 165-ball FBGA Package related information).<br>Updated <a href="#">Package Diagrams</a> :<br>Removed spec 51-85180 *C. |
| *M                                                                                                               | 3753416 | PRIT            | 09/24/2012      | Updated <a href="#">Package Diagrams</a> :<br>spec 51-85115 – Changed revision from *C to *D.<br>Completing Sunset Review.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |

**Document History Page** *(continued)*

| Document Title: CY7C1361C/CY7C1363C, 9-Mbit (256K × 36/512K × 18) Flow-Through SRAM<br>Document Number: 38-05541 |         |                 |                 |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
|------------------------------------------------------------------------------------------------------------------|---------|-----------------|-----------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Rev.                                                                                                             | ECN No. | Orig. of Change | Submission Date | Description of Change                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
| *N                                                                                                               | 4112732 | PRIT            | 09/03/2013      | Updated <a href="#">Ordering Information</a> (Updated part numbers).<br>Updated to new template.<br>Completing Sunset Review.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
| *O                                                                                                               | 4430353 | PRIT            | 07/08/2014      | Updated <a href="#">Features</a> :<br>Included 165-ball FBGA Package related information.<br>Updated <a href="#">Pin Configurations</a> :<br>Included 165-ball FBGA Package related information (Added <a href="#">Figure 4</a> ).<br>Added <a href="#">Boundary Scan Order</a> (Corresponding to 165-ball FBGA Package).<br>Updated <a href="#">Capacitance</a> :<br>Included 165-ball FBGA Package related information.<br>Updated <a href="#">Thermal Resistance</a> :<br>Included 165-ball FBGA Package related information.<br>Updated <a href="#">Ordering Information</a> (Updated part numbers).<br>Updated <a href="#">Package Diagrams</a> :<br>spec 51-85050 – Changed revision from *D to *E.<br>Added spec 51-85180 *F. |
| *P                                                                                                               | 4574263 | PRIT            | 11/19/2014      | Updated <a href="#">Functional Description</a> :<br>Added “For a complete list of related documentation, click <a href="#">here</a> .” at the end.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
| *Q                                                                                                               | 4973995 | PRIT            | 10/19/2015      | Updated <a href="#">Package Diagrams</a> :<br>spec 51-85180 – Changed revision from *F to *G.<br>Updated to new template.<br>Completing Sunset Review.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |
| *R                                                                                                               | 5331538 | PRIT            | 06/30/2016      | Updated <a href="#">Truth Table</a> :<br>Updated details in “CE <sub>3</sub> ” column corresponding to “Deselected cycle, power-down”.<br>Updated to new template.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
| *S                                                                                                               | 5515297 | PRIT            | 11/09/2016      | Updated <a href="#">Ordering Information</a> :<br>No change in part numbers.<br>Added a column “Status” and added MPN status details in that column.<br>Added Note “This MPN is not recommended for new designs.” and referred the same note in MPN “CY7C1363C-133AJXI”.<br>Updated <a href="#">Package Diagrams</a> :<br>spec 51-85050 – Changed revision from *E to *F.<br>Removed spec 51-85115 *D.<br>Updated to new template.<br>Completing Sunset Review.                                                                                                                                                                                                                                                                      |
| *T                                                                                                               | 6026123 | RMES            | 01/11/2018      | Updated <a href="#">Ordering Information</a> :<br>Updated part numbers.<br>Removed Note “This MPN is not recommended for new designs.” and its reference.<br>Updated <a href="#">Package Diagrams</a> :<br>spec 51-85050 – Changed revision from *F to *G.<br>Updated to new template.<br>Completing Sunset Review.                                                                                                                                                                                                                                                                                                                                                                                                                  |
| *U                                                                                                               | 6524559 | RMES            | 03/28/2019      | Updated <a href="#">Ordering Information</a> :<br>Updated part numbers.<br>Updated to new template.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |

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### Cypress Developer Community

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### Technical Support

[cypress.com/support](http://cypress.com/support)

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